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# HA12216F/HA12221F Series

Audio Signal Processor for Car Deck  
(Decode only Dolby B type NR with PB Amp.)

## HITACHI

ADE-207-254E (Z)

6th Edition  
Dec. 2000

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### Description

HA12216F/HA12221F series are silicon monolithic bipolar IC providing Dolby B type noise reduction, music sensor, PB equalizer system in one chip.

- Note:
1. Dolby is a trademark of Dolby Laboratories Licensing Corporation.  
A license from Dolby Laboratories Licensing Corporation is required for the use of this IC.
  2. HA12221F series does not include Dolby B NR.

### Functions

- PB equalizer × 2 channel
- Music sensor × 1 channel
- Dolby B NR (Only HA12216F series) × 2 channel
- Line mute (Tape radio) SW × 2 channel

### Features

- Different type of PB equalizer characteristics selection (120  $\mu$ s/70  $\mu$ s) is available with fully electronic control switching built-in.
- Changeable to Forward, Reverse-mode for PB head with fully electronic control switching built-in.
- Available to change music sensing level by external resistor.
- Available to change response of music sensor by external capacitor.
- Music sensing level, built-in switch to change a band (MSG<sub>v</sub>).
- NR ON/OFF fully electronic control switching built-in. (Only HA12216F series)
- Line mute (Tape radio) control switching built-in.
- Available to connect direct with MPU.
- These ICs are strong for a cellular phone noise. (18 dB improvement from HA12163)

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# HA12216F/HA12221F Series

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## Ordering Information

### Operating Voltage

Product	Min	Max	Unit
HA12216F/HA12221F	6.5	12	V
HA12217F/HA12222F	6.8	12	V
HA12218F/HA12223F	7.2	12	V

Note: 1. These ICs are designed to operate on single supply.  
2. HA12217F and HA12218F, HA12222F and HA12223F are develop, there meets comply with your demands.

### Standard Level

Product	Package	PB-OUT Level
HA12216F/HA12221F	FP-40	300 mVrms
HA12217F/HA12222F	FP-40	387.5 mVrms
HA12218F/HA12223F	FP-40	450 mVrms

### Function

Product	PB-EQ	Music Sensor	Mute	Dolby B NR
HA12216F series	○	○	○	○
HA12221F series	○	○	○	×

### Parallel-Data Format

Pin No.	Pin Name	Lo	Hi
10	TAPE/RADIO	TAPE	RADIO
11*	NR ON/OFF	NR OFF	NR ON
12	120 $\mu$ /70 $\mu$	120 $\mu$ (Normal)	70 $\mu$ (Metal or Chrome)
13	Forward/Reverse	Forward	Reverse
14	Search/Repeat	Search (FF or REV)	Repeat (Normal Speed)

Note: Non connection regarding HA12221F series.

# HA12216F/HA12221F Series

**Pin Description, Equivalent Circuit** ( $V_{CC} = 9\text{ V}$ , A system of single supply voltage,  $T_a = 25^\circ\text{C}$ , No Signal, The value in the show typical value.)

Pin No.	Terminal Name	Note	Equivalent Circuit	Pin Description
18	MSI	$V = V_{CC}/2$		MS input *1
28	TAI (L)			Tape input
3	TAI (R)			
26	RAI (L)			Radio input (Mute)
5	RAI (R)			
23 *2	DET (L)	$V = 2.5\text{V}$		Time constant pin for rectifier
8 *2	DET (R)			
33	RIP	$V = V_{CC}/2$		Ripple filter
4 *2	Bias	$V = 0.28\text{V}$		Dolby bias current input
17	MSDET	—		Time constant pin for rectifier

- Note: 1. MS: Music Sensor  
 2. Non connection regarding HA12221F series.

# HA12216F/HA12221F Series

**Pin Description, Equivalent Circuit** ( $V_{CC} = 9\text{ V}$ , A system of single supply voltage,  $T_a = 25^\circ\text{C}$ , No Signal, The value in the show typical value.) (cont)

Pin No.	Terminal Name	Note	Equivalent Circuit	Pin Description
25	PBOUT (L)	$V = V_{CC}/2$		PB output
6	PBOUT (R)			
19	MAOUT	$V = V_{CC}/2$		MS amp. output *1
38	VREF			Reference output
29	EQOUT (L)			Equalizer output (120μ)
2	EQOUT (R)			
30	M-OUT (L)	$V = V_{CC}/2$		Equalizer output (70μ)
1	M-OUT (R)			
16	$V_{CC}$	—		Power supply
7	NC	—		No connection
9				
22				
24				
27				

Note: 1. MS: Music Sensor

# HA12216F/HA12221F Series

**Pin Description, Equivalent Circuit** ( $V_{CC} = 9\text{ V}$ , A system of single supply voltage,  $T_a = 25^\circ\text{C}$ , No Signal, The value in the show typical value.) (cont)

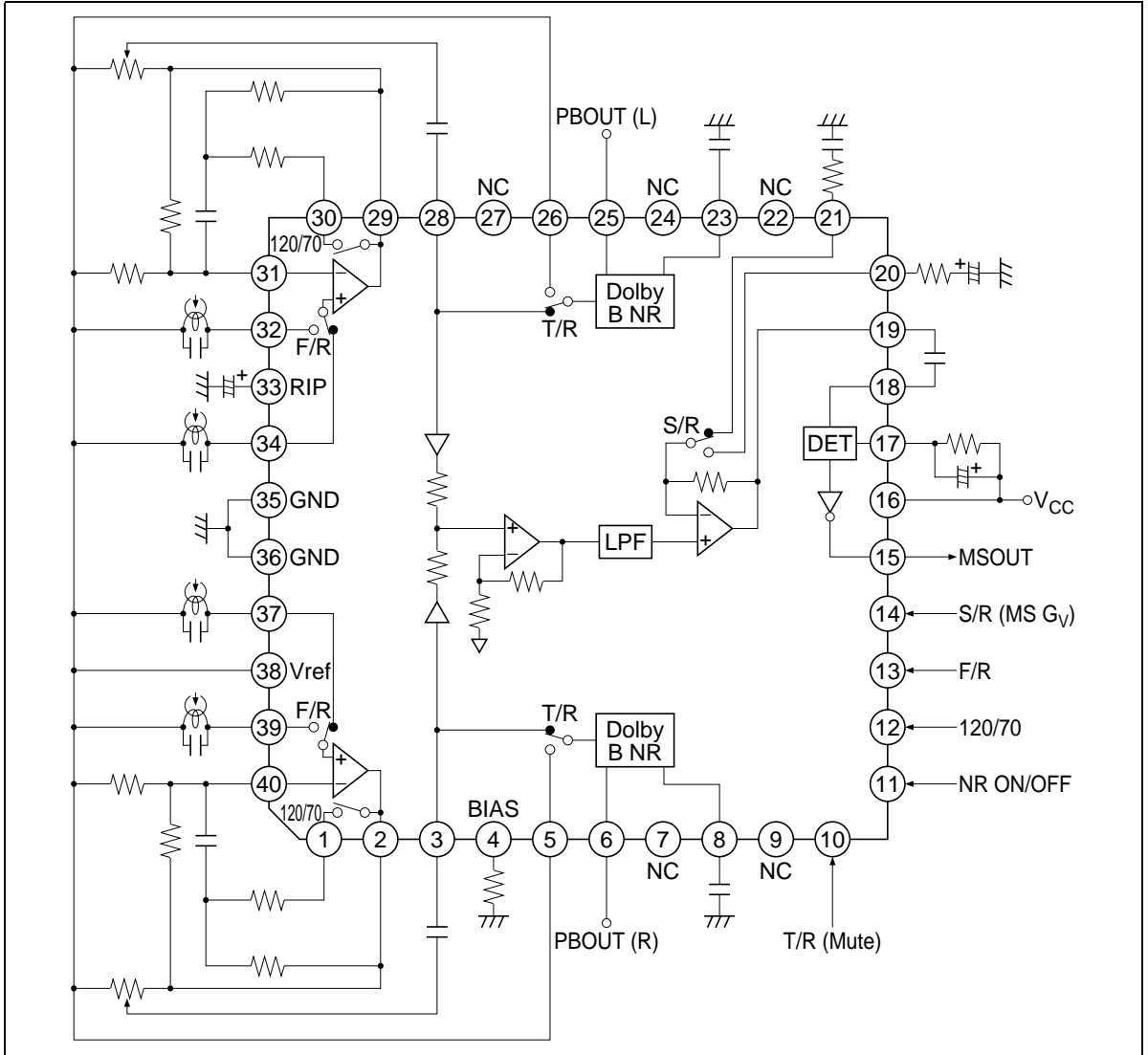
Pin No.	Terminal Name	Note	Equivalent Circuit	Pin Description
34	FIN (L)	—		Equalizer input (Forward)
37	FIN (R)			
32	RIN (L)			Equalizer input (Reverse)
39	RIN (R)			
31	NFI (L)			Negative feedback
40	NFI (R)			
10	T/R (Mute)	—		Mode control input
11 *2	NR ON/OFF			
12	120/70			
13	F/R			
14	S/R (MS $G_V$ )			
15	MSOUT	—		MS output (to MPU) *1
20	MS $G_V$ (R)	$V = V_{CC}/2$		MS gain terminal *1
21	MS $G_V$ (S)			
35	GND	—		GND pin
36				

Note: 1. MS: Music Sensor  
2. Non connection regarding HA12221F series.

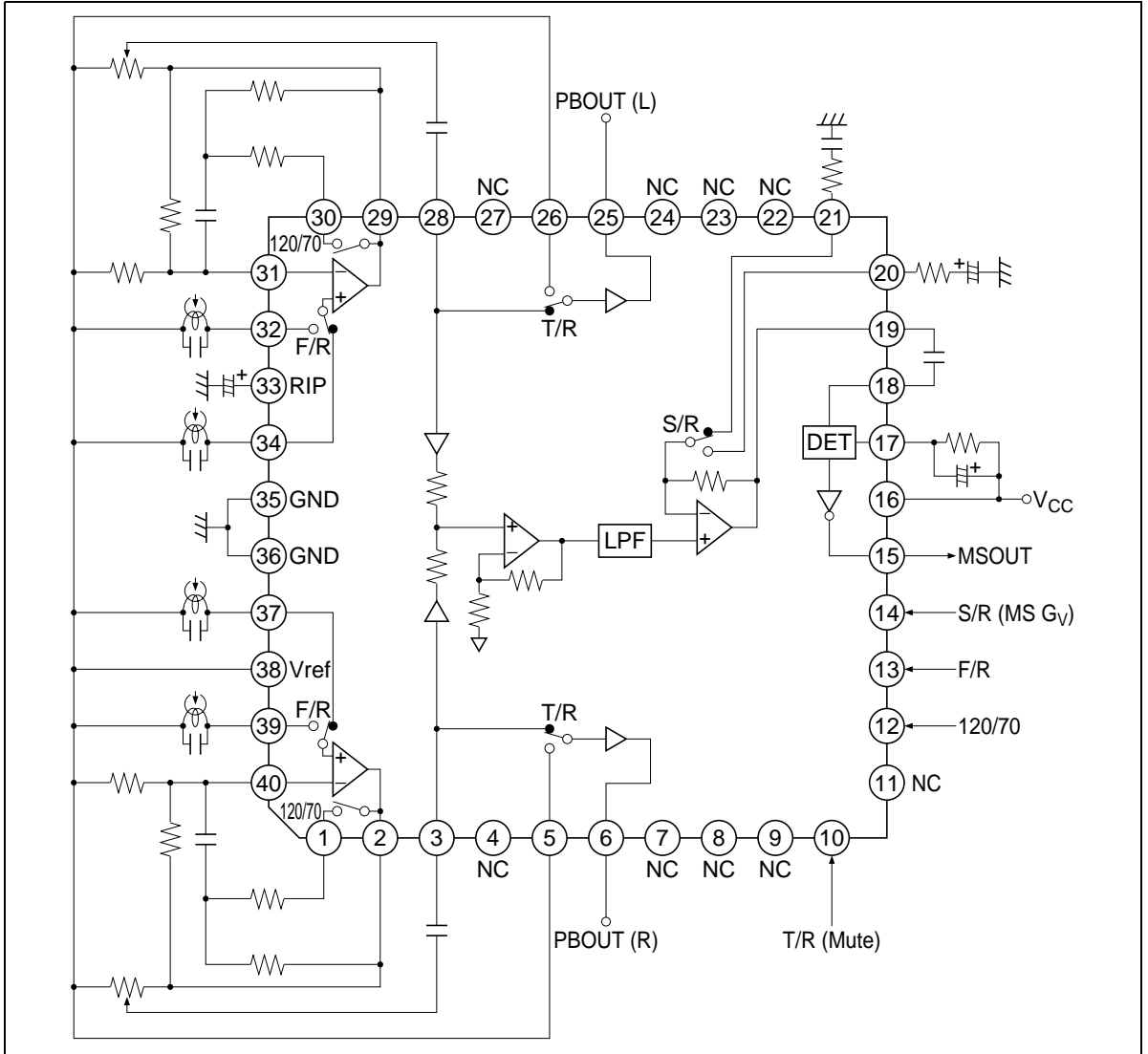
# HA12216F/HA12221F Series

## Block Diagram

### HA12216F Series



HA12221F Series



# HA12216F/HA12221F Series

## Functional Description

### Power Supply Range

HA12216F/HA12221F series are provided with three line output level, which will permit on optimum overload margin for power supply conditions. And these are designed to operate on single supply only.

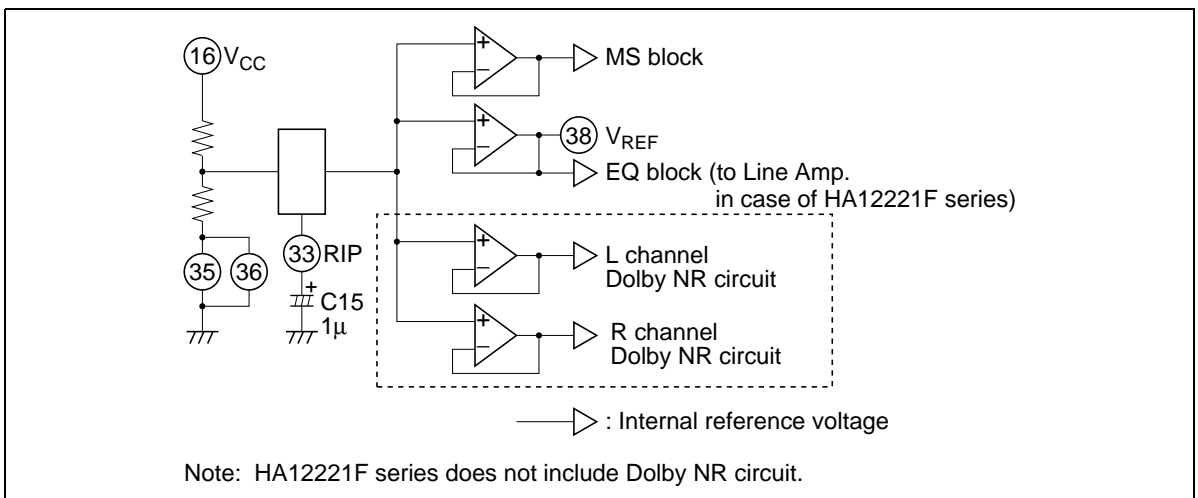
**Table 1 Supply Voltage Range**

Product	Single Supply
HA12216F/HA12221F	6.5 V to 12.0 V
HA12217F/HA12222F	6.8 V to 12.0 V
HA12218F/HA12223F	7.2 V to 12.0 V

Note: The lower limit of supply voltage depends on the line output reference level.  
The minimum value of the overload margin is specified as 12 dB by Dolby Laboratories.

### Reference Voltage

These devices provide the reference voltage of half the supply voltage that is the signal grounds. As the peculiarity of these devices, the capacitor for the ripple filter is very small about 1/100 compared with their usual value. The block diagram is shown as figure 1.



**Figure 1 The Block Diagram of Reference Supply Voltage**



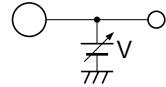
## Operating Mode Control

HA12216F/HA12221F series provides fully electronic switching circuits. And each operating mode control are controlled by parallel data (DC voltage).

When a power supply of this IC is cut off, for a voltage, in addition to a mode control terminal even though as do not destruct it, in series for resistance.

**Table 2**      **Threshold Voltage ( $V_{TH}$ )**

Pin No.	Lo	Hi	Unit	Test Condition
10, 11*, 12, 13, 14	-0.2 to 1.0	3.5 to $V_{CC}$	V	Input Pin    Measure



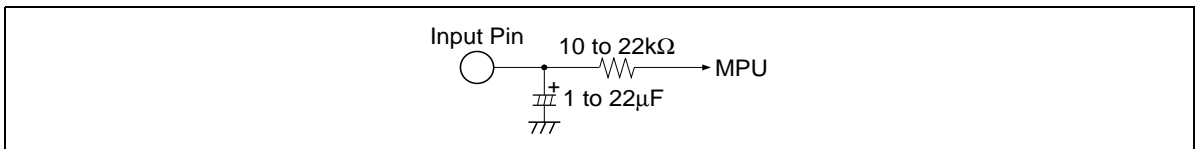
Note: \* Non connection regarding HA12221F series.

**Table 3**      **Switching Truth Table**

Pin No.	Lo	Hi
10	TAPE	RADIO
11*	NR OFF	NR ON
12	120 $\mu$ (Normal)	70 $\mu$ (Metal or Chrome)
13	FORWARD	REVERSE
14	SER (FF or REV)	REP (Normal Speed)

Notes: \* Non connection regarding HA12221F series.

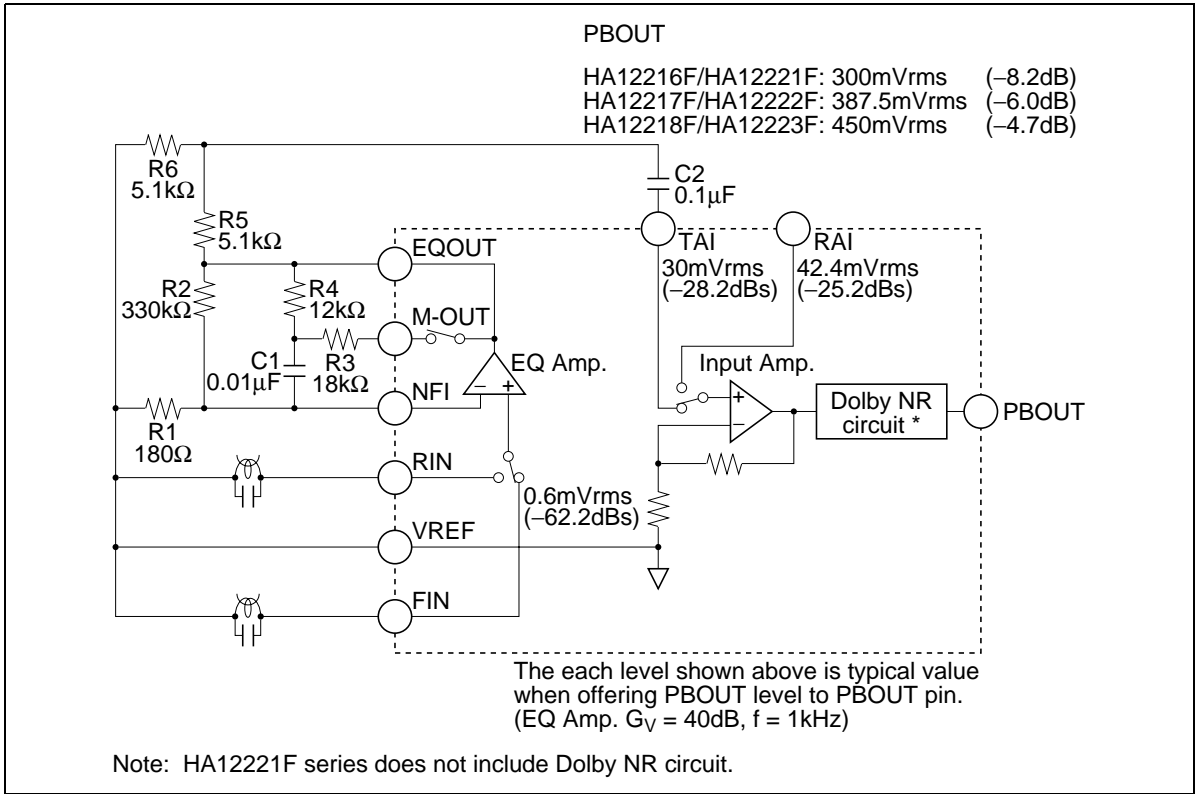
1. Each pins are on pulled down with 100 k $\Omega$  internal resistor. Therefore, it will be low-level when each pins are open.
2. Over shoot level and under shoot level of input signal must be the standardized. (High:  $V_{CC}$ , Low: -0.2 V)
3. Reducing pop noise is so much better for 10 k $\Omega$  to 22 k $\Omega$  resistor and 1  $\mu$ F to 22  $\mu$ F capacitor shown figure 2.



**Figure 2**      **Interface for Reduction of Pop Noise**

# HA12216F/HA12221F Series

## Input Block Diagram and Level Diagram



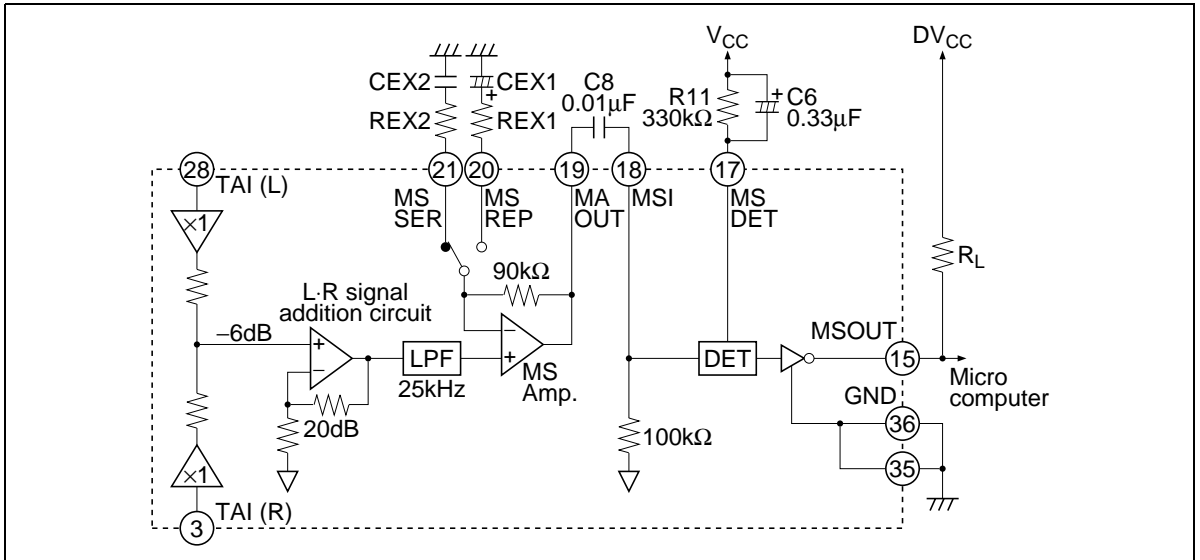
**Figure 3 Input Block Diagram**

### Adjustment of Playback Reference Operate Level

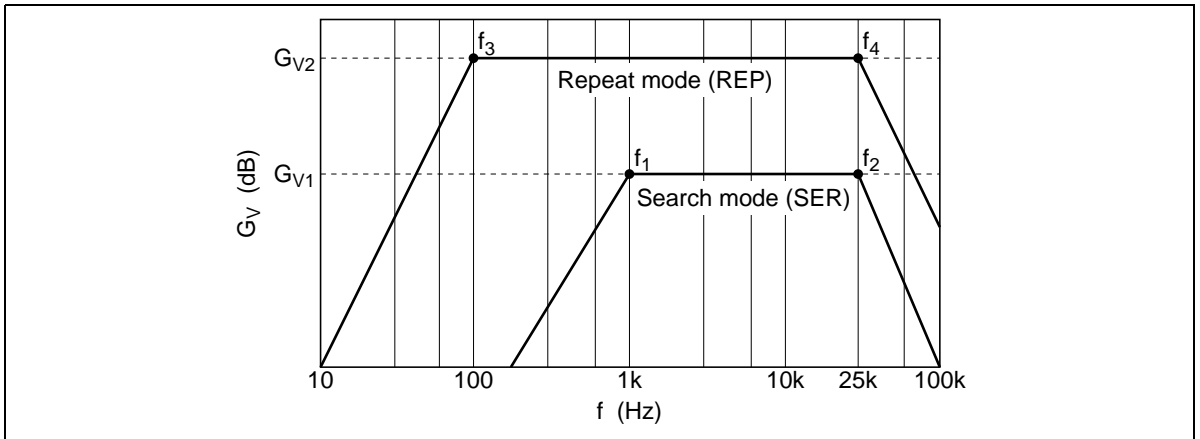
After replace R5 and R6 with a half-fix volume of 10 kΩ, adjust playback reference operate level.

**The Sensitivity Adjustment of Music Sensor**

Adjusting MS Amp. gain by external resistor, the sensitivity of music sensor can set up. The music sensor block diagram is shown in figure 4, and frequency response is shown in figure 5.



**Figure 4 Music Sensor Block Diagram**



**Figure 5 Frequency Response**

# HA12216F/HA12221F Series

## 1. Search mode

$$G_{V1} = 20\text{dB} + 20\log\left(1 + \frac{90\text{k}}{\text{REX2}}\right) \text{ [dB]}$$

$$f_1 = \frac{1}{2\pi \cdot \text{CEX2} \cdot \text{REX2}} \text{ [Hz]}, f_2 = 25\text{k} \text{ [Hz]}$$

## 2. Repeat mode

$$G_{V2} = 20\text{dB} + 20\log\left(1 + \frac{90\text{k}}{\text{REX1}}\right) \text{ [dB]}$$

$$f_3 = \frac{1}{2\pi \cdot \text{CEX1} \cdot \text{REX1}} \text{ [Hz]}, f_4 = 25\text{k} \text{ [Hz]}$$

$G_{VIA}$ : L·R signal addition circuit gain.

The sensitivity of music sensor (S) is computed by the formula mentioned below.

$$S = -\left(G_V \cdot 1 - 20\log\frac{130^{*3}}{30^{*2}}\right) = 12.7 - G_V \text{ [dB]}$$

- Note:
1. Search mode:  $G_{V1}$ , Repeat mode:  $G_{V2}$
  2. Standard level of TAI pin (Dolby level correspondence) = 30 mVrms
  3. Standard sensing level of music sensor = 130 mVrms

Item	REX1, 2	CEX1, 2	$G_{V1,2}$	$f_{1,3}$	$f_{2,4}$	S (one side channel)	S (both channel)
Search mode	24 k $\Omega$	0.01 $\mu$ F	33.5 dB	663 Hz	25 kHz	-14.8 dB	-20.8 dB
Repeat mode	2.4 k $\Omega$	1 $\mu$ F	51.7 dB	66.3 Hz	25 kHz	-33.0 dB	-39.0 dB

Note: S is 6 dB down in case of one-side channel. And this MS presented hysteresis lest MSOUT terminal should turn over again Hi level or Lo level, in case of thresh S level constantly.

## Music Sensor Time Constant

1. Sensing no signal to signal (Attack) is determined by C6, 0.01  $\mu$ F to 1  $\mu$ F capacitor C6 can be applicable.
2. Sensing signal to no signal (Recovery) is determined by C6 and R11, however preceding (1), 100 k $\Omega$  to 1 M $\Omega$  can be applicable.

## Music Sensor Output (MSOUT)

As for the internal circuit of music sensor block, music sensor output pin is connected to the collector of NPN type directly, therefore, output level will be “high” when sensing no signal. And output level will be “low” when sensing signal.

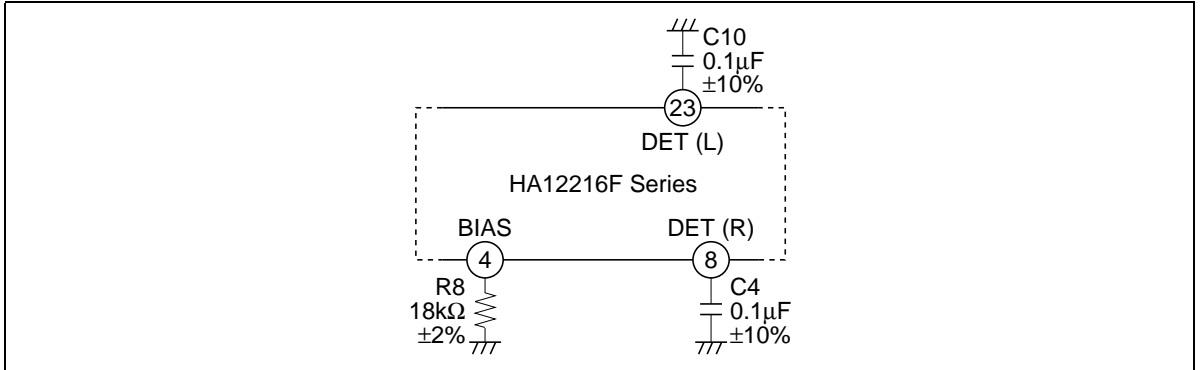
$$I_L = \frac{DV_{CC} - \text{MSOUT}_{LO}^*}{R_L}$$

\*  $\text{MSOUT}_{LO}$  : Sensing signal (about 1V)

Note: 1. Supply voltage of MSOUT pin must be less than  $V_{CC}$  voltage.

## The Tolerances of External Components for Dolby NR (Only HA12216F Series)

For adequate Dolby NR tracking response, take external components shown below.  
Also, leak is small capacity, and please employ a good quality object.



**Figure 6 Tolerance of External Components**

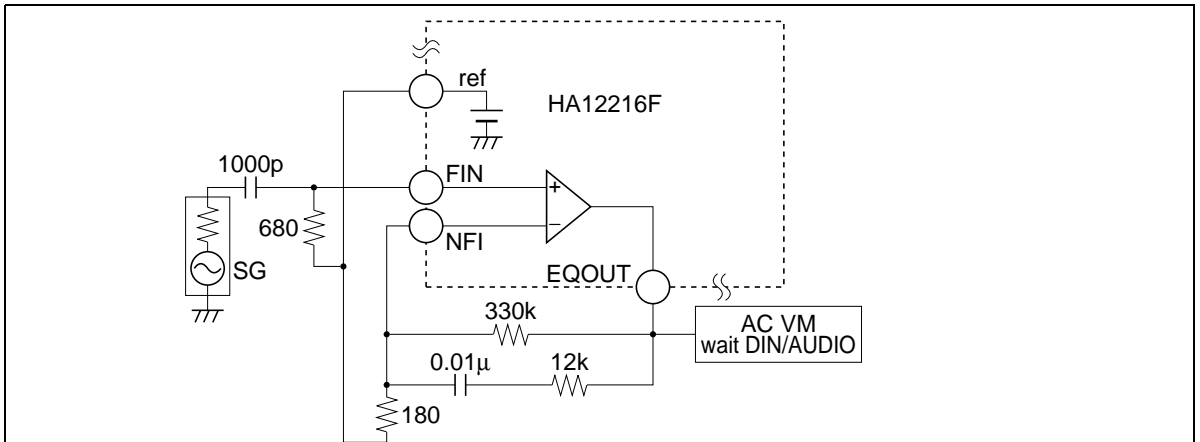
## Countermeasure of a Cellular Phone Noise

This IC have reinforced a cellular phone noise countermeasure, to show it hereinafter.

However, it is presumed that this effect change it greatly, by a mount set.

Please sufficiently examine an arrangement of positions, shield method, wiring pattern, in order to obtain a maximum effect.

A high terminal of a noise sensitivity of this IC is FIN, RIN, NFI and RIP.



Note: Test condition

- Use for SG by cellular radio for an evaluation use.
- SG output mode
  - PDC system, burst
  - UP Tch (Transmission mode on the side of a movement machine)
- To evaluate a capacitor of 1000 pF as connecting with it directly.
- About EQOUT output, what you measure through DIN/AUDIO filter.

**Figure 7 Test Circuit**

# HA12216F/HA12221F Series

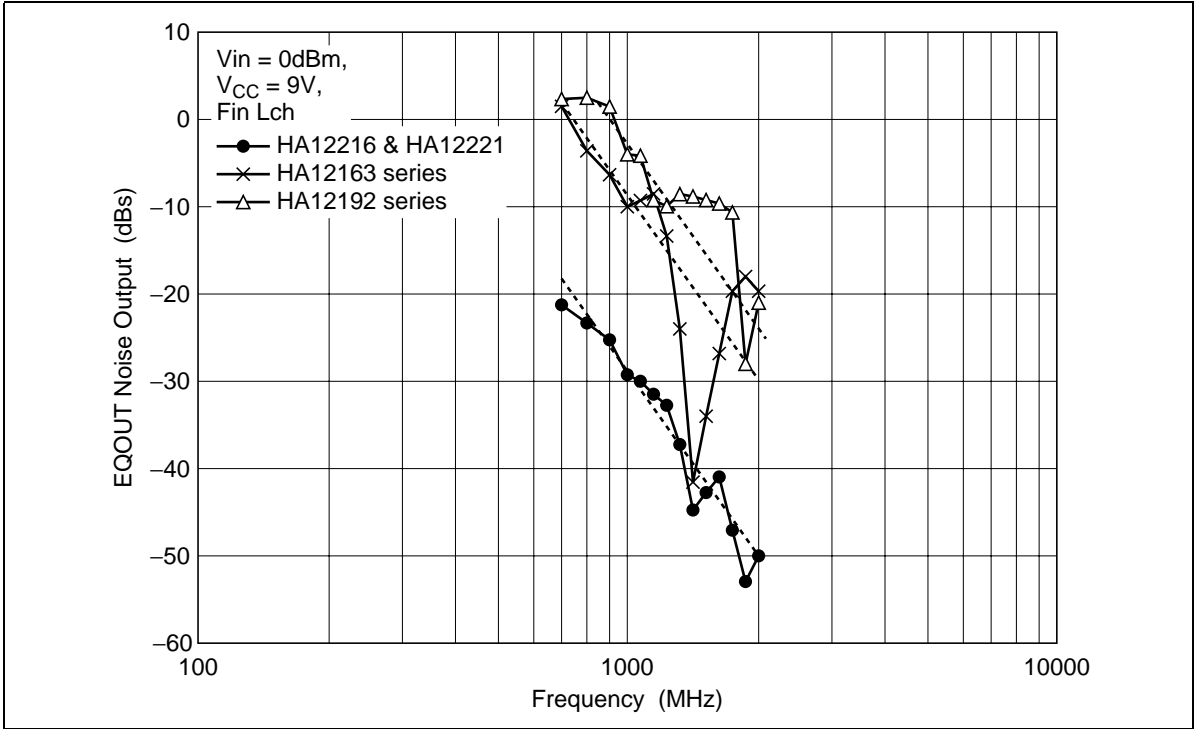


Figure 8 EQOUT Noise Output vs. Transmission Frequency Characteristic

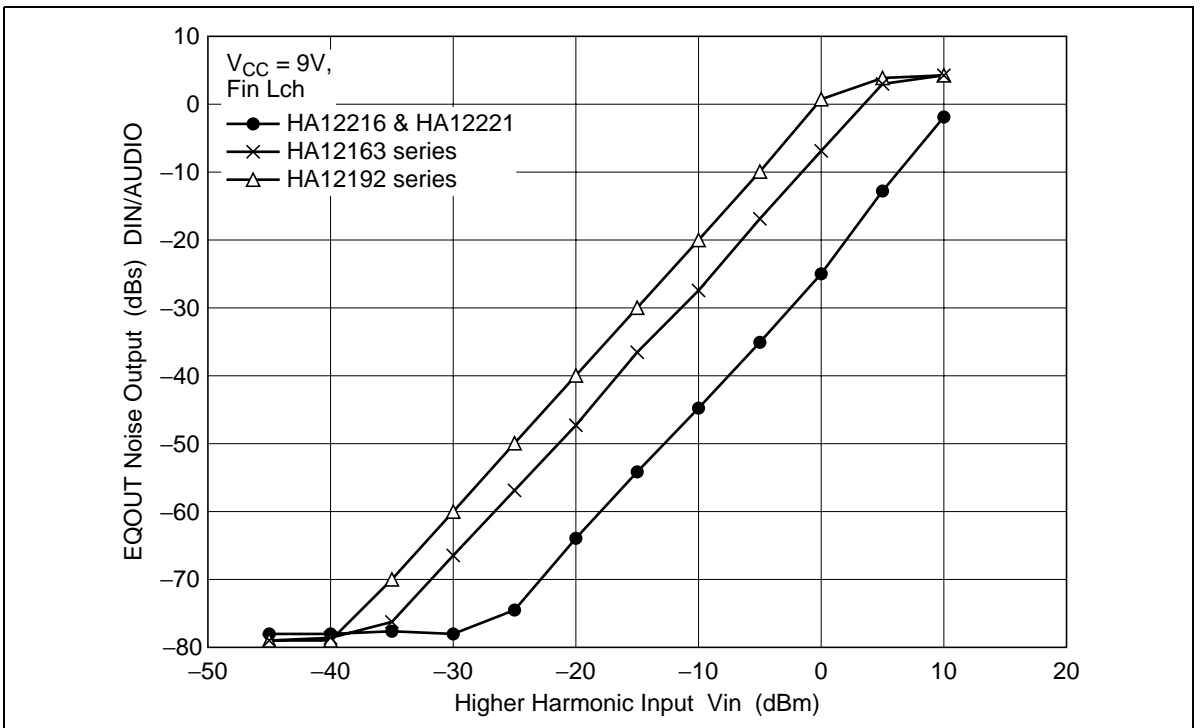


Figure 9 EQOUT Noise Output vs. Transmission

**Absolute Maximum Ratings** (Ta = 25°C)

<b>Item</b>	<b>Symbol</b>	<b>Rating</b>	<b>Unit</b>	<b>Note</b>
Maximum supply voltage	V <sub>cc</sub> Max	16	V	
Power dissipation	Pd	400	mW	Ta ≤ 85°C
Operating temperature	Topr	-40 to +85	°C	
Storage temperature	Tstg	-55 to +125	°C	

# HA12216F/HA12221F Series

## Electrical Characteristics

### HA12216F Series

(Ta = 25°C, V<sub>CC</sub> = 9.0 V, PBOULT Level 300 mVrms(HA12216F) 387.5 mVrms(HA12217F) 450 mVrms(HA12218F))

Item	Symbol	Test Condition										Min	Typ	Max	Unit	Application Terminal						Remark	
		IC Condition					IC Condition									Input		Output					
		NR ON/OFF	120μ/70μ	F/R	T/R	S/R	F	T	S	Input	Output					fin (Hz)	PBOULT level (dB)	R	L	R	L		
Quiescent current	I <sub>Q</sub>	ON	—	—	—	—	—	—	—	—	—	—	4.0	9.5	15.0	mA	—	—	—	—	16		
Input Amp. gain	G <sub>1/2</sub> A TAI	OFF	—	—	T	—	TAI	PBOULT	—	—	1k	0	18.8	19.8	20.8	dB	3	28	6	25			
	G <sub>1/2</sub> A RAI	OFF	—	—	R	—	RAI	PBOULT	—	—	1k	0	15.8	16.8	17.8		5	26					
	G <sub>1/2</sub> A TAI	OFF	—	—	T	—	TAI	PBOULT	—	—	1k	0	21.2	22.2	23.2		3	28					
	G <sub>1/2</sub> A RAI	OFF	—	—	R	—	RAI	PBOULT	—	—	1k	0	18.2	19.2	20.2		5	26					
	G <sub>1/2</sub> A TAI	OFF	—	—	T	—	TAI	PBOULT	—	—	1k	0	22.5	23.5	24.5		3	28					
	G <sub>1/2</sub> A RAI	OFF	—	—	R	—	RAI	PBOULT	—	—	1k	0	19.5	20.5	21.5		5	26					
B-type decode cut	DEC-2k (1)	ON	—	—	T	—	TAI	PBOULT	—	—	2k	-20	2.8	4.3	5.8	dB	3	28	6	25			
	DEC-2k (2)	ON	—	—	T	—	TAI	PBOULT	—	—	2k	-30	7.0	8.5	10.0								
	DEC-5k (1)	ON	—	—	T	—	TAI	PBOULT	—	—	5k	-20	1.7	3.2	4.7								
	DEC-5k (2)	ON	—	—	T	—	TAI	PBOULT	—	—	5k	-30	6.7	8.2	9.7								
PBOULT offset	VoIs	OFF	—	—	T↔R	—	—	PBOULT	—	—	—	—	-150	0.0	150	mV	3	28	6	25			
Signal handling	Vo max	ON	—	—	T	—	TAI	PBOULT	—	—	1k	—	12.0	13.0	—	dB	3	28	6	25	1		
Signal to noise ratio	S/N	ON	—	—	T	—	TAI	PBOULT (1k)	—	—	(0)	(0)	70.0	80.0	—	dB	(3)	(28)	6	25			
T.H.D.	THD	ON	—	—	T	—	TAI	PBOULT 1k	—	—	0	0	—	0.05	0.3	%	3	28	6	25			
Channel separation	CT RL (1)	OFF	—	—	R	—	RAI	PBOULT 1k	—	—	1k	(+12)	70.0	80.0	—	dB	3	28	6→25	25→6			
	CT RL (2)	OFF	120μ	F	T	—	FIN	PBOULT 1k	—	—	1k	(+12)	50.0	60.0	—		37	34	6	25			
Crosstalk	CT EQ→RAI	OFF	120μ	F	T→R	—	FIN	PBOULT 1k	—	—	1k	(+12)	70.0	80.0	—	dB	37	34	6	25			
	CT RAI→EQ	OFF	120μ	F	R→T	—	RAI	PBOULT 1k	—	—	1k	(+12)	50.0	60.0	—		5	26	6	25			
PB-EQ gain	G <sub>V</sub> EQ 1k	—	120μ	F/R	—	—	FIN/RIN	EQOUT 1k	—	—	1k	—	Vin=0.6mVrms	37.0	40.0	43.0	dB	37/39	34/32	2	29		
	G <sub>V</sub> EQ 10k(1)	—	120μ	F	—	—	FIN	EQOUT 10k	—	—	10k	—	33.0	36.0	39.0		37	34					
	G <sub>V</sub> EQ 10k(2)	—	70μ	F	—	—	FIN	EQOUT 10k	—	—	10k	—	29.0	32.0	35.0		37	34					
PB-EQ Max output level	V <sub>OM</sub>	—	120μ	F/R	—	—	FIN	EQOUT 1k	—	—	1k	—	THD=1%	300	600	—	mVrms	37/39	34/32	2	29	1	
PB-EQ THD	THD-EQ	—	120μ	F/R	—	—	FIN/RIN	EQOUT 1k	—	—	1k	—	Vin=3mVrms	—	0.1	0.3	%	37/39	34/32	2	29		
Noise level converted in input	V <sub>N</sub>	—	120μ	F/R	—	—	FIN/RIN	EQOUT (1k)	—	—	1k	—	Rg=680Ω, DIN-AUDIO	—	0.7	1.5	μVrms	(37/39)	(34/32)	2	29		
MS sensitivity level	V <sub>ON</sub> (1)	—	—	—	T	R	TAI	PBOULT 5k	—	—	5k	—	-36	-32	-28	dB	3	28	2	29	15		
	V <sub>ON</sub> (2)	—	—	—	T	S	TAI	PBOULT 5k	—	—	5k	—	-18	-14	-10								
MS output low level	V <sub>OL</sub>	—	—	—	T	S	TAI	MSOUT 5k	—	—	5k	0	—	1.0	1.5	V	3	28	—	—	15		
MS output leak current	I <sub>OH</sub>	—	—	—	—	—	—	MSOUT	—	—	—	—	No signal	—	0.0	2.0	μA	—	—	—	15		
Control voltage	V <sub>IL</sub>	—	—	—	—	—	—	—	—	—	—	—	-0.2	—	1.0	V	—	—	—	—	—	10 to 14	
	V <sub>IH</sub>	—	—	—	—	—	—	—	—	—	—	—	3.5	—	V <sub>CC</sub>		—	—	—	—	—		

Note: 1. HA12216F: V<sub>CC</sub> = 6.5V  
 HA12217F: V<sub>CC</sub> = 6.8V  
 HA12218F: V<sub>CC</sub> = 7.2V



## HA12221F Series

(Ta = 25°C, V<sub>CC</sub> = 9.0 V, P<sub>BOU</sub>T Level 300 mVrms(HA12221F) 387.5 mVrms(HA12222F) 450 mVrms(HA12223F))

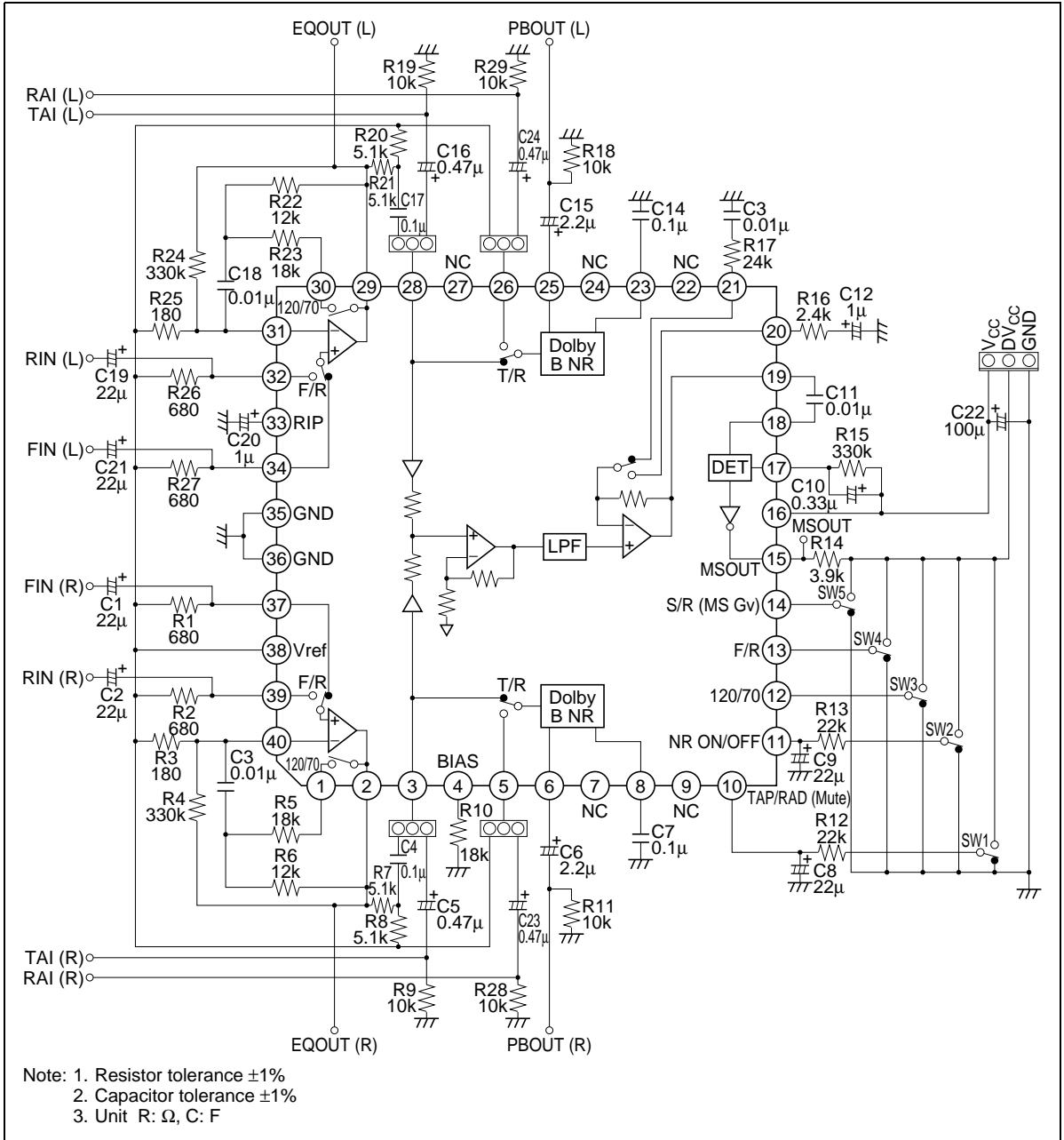
Item	Symbol	Test Condition										Application Terminal						Remark			
		IC Condition					Test Condition					Input			Output						
		120μ/70μ	F/R	T/R	S/R	T/S	Input	Output	f <sub>in</sub> (Hz)	P <sub>BOU</sub> T level (dB)	Min	Typ	Max	Unit	R	L	R		L		
Quiescent current	I <sub>Q</sub>	70μ	F	T	S	—	—	—	—	—	No signal	—	—	3.0	5.0	8.0	mA	—	—	—	16
Input Amp. gain	G <sub>V</sub> /A TAI	—	—	T	—	TAI	P <sub>BOU</sub> T	1k	0	—	—	—	—	19.0	20.0	21.0	dB	3	28	6	25
	G <sub>V</sub> /A RAI	—	—	R	—	RAI	P <sub>BOU</sub> T	1k	0	—	—	—	—	16.0	17.0	18.0	dB	5	26	—	—
	G <sub>V</sub> /A TAI	—	—	T	—	TAI	P <sub>BOU</sub> T	1k	0	—	—	—	—	21.2	22.2	23.2	dB	3	28	—	—
	G <sub>V</sub> /A RAI	—	—	R	—	RAI	P <sub>BOU</sub> T	1k	0	—	—	—	—	18.2	19.2	20.2	dB	5	26	—	—
	G <sub>V</sub> /A TAI	—	—	T	—	TAI	P <sub>BOU</sub> T	1k	0	—	—	—	—	22.5	23.5	24.5	dB	3	28	—	—
	G <sub>V</sub> /A RAI	—	—	R	—	RAI	P <sub>BOU</sub> T	1k	0	—	—	—	—	19.5	20.5	21.5	dB	5	26	—	—
P <sub>BOU</sub> T offset	V <sub>ofs</sub>	—	—	T↔R	—	—	P <sub>BOU</sub> T	—	—	—	V <sub>CC</sub> =12V, No signal	—	—	-15.0	0.0	15.0	mV	3	28	6	25
Signal handling	V <sub>o max</sub>	—	—	T	—	TAI	P <sub>BOU</sub> T	1k	—	—	THD=1%	—	—	12.0	13.0	—	dB	3	28	6	25
Signal to noise ratio	S/N	—	—	T	—	TAI	P <sub>BOU</sub> T	(1k)	(0)	—	R <sub>g</sub> =10kΩ, CCIR/ARM	—	—	70.0	80.0	—	dB	(3)	(28)	6	25
T.H.D.	THD	—	—	T	—	TAI	P <sub>BOU</sub> T	1k	0	—	—	—	—	—	0.05	0.3	%	3	28	6	25
Channel separation	CT RL (1)	—	—	R	—	RAI	P <sub>BOU</sub> T	1k	(+12)	—	—	—	—	70.0	80.0	—	dB	3	28	6	25
	CT RL (2)	—	—	T	—	FIN	P <sub>BOU</sub> T	1k	(+12)	—	—	—	—	50.0	60.0	—	dB	37	34	—	—
Crosstalk	CT EQ→RAI	120μ	F	T→R	—	FIN	P <sub>BOU</sub> T	1k	(+12)	—	—	—	—	70.0	80.0	—	dB	5	26	—	—
	CT RAI→EQ	120μ	F	R→T	—	RAI	P <sub>BOU</sub> T	1k	(+12)	—	—	—	—	50.0	60.0	—	dB	5	26	—	—
	G <sub>V</sub> EQ 1k	120μ	F/R	—	—	FIN/RIN	EQOUT	1k	—	—	V <sub>in</sub> =0.6mVrms	—	—	37.0	40.0	43.0	dB	37/39	34/32	2	29
PB-EQ gain	G <sub>V</sub> EQ 10k(1)	120μ	F	—	—	FIN	EQOUT	10k	—	—	—	—	—	33.0	36.0	39.0	dB	37	34	—	—
	G <sub>V</sub> EQ 10k(2)	70μ	F	—	—	FIN	EQOUT	10k	—	—	—	—	—	29.0	32.0	35.0	dB	37	34	—	—
	V <sub>OM</sub>	120μ	F/R	—	—	FIN	EQOUT	1k	—	—	THD=1%	—	—	300	600	—	mVrms	37/39	34/32	2	29
PB-EQ THD	THD-EQ	120μ	F/R	—	—	FIN/RIN	EQOUT	1k	—	—	V <sub>in</sub> =3mVrms	—	—	—	0.1	0.3	%	37/39	34/32	2	29
Noise level converted in input	V <sub>N</sub>	120μ	F/R	—	—	FIN/RIN	EQOUT	(1k)	—	—	R <sub>g</sub> =680Ω, DIN-AUDIO	—	—	—	0.7	1.5	μVrms	(37/39)	(34/32)	2	29
MS sensitivity level	V <sub>ON</sub> (1)	—	—	T	R	TAI	P <sub>BOU</sub> T	5k	—	—	—	—	—	-36	-32	-28	dB	3	28	2	29
	V <sub>ON</sub> (2)	—	—	T	S	TAI	P <sub>BOU</sub> T	5k	—	—	—	—	—	-18	-14	-10	dB	—	—	—	—
MS output low level	V <sub>OL</sub>	—	—	T	S	TAI	MSOUT	5k	0	—	—	—	—	—	1.0	1.5	V	3	28	—	—
MS output leak current	I <sub>OH</sub>	—	—	—	—	—	MSOUT	—	—	—	No signal	—	—	—	0.0	2.0	μA	—	—	—	—
Control voltage	V <sub>IL</sub>	—	—	—	—	—	—	—	—	—	—	—	—	-0.2	—	—	V	—	—	—	—
	V <sub>IH</sub>	—	—	—	—	—	—	—	—	—	—	—	—	3.5	—	—	V <sub>CC</sub>	—	—	—	10 to 14

Note: 1. HA12221F: V<sub>CC</sub> = 6.5V  
 HA12222F: V<sub>CC</sub> = 6.8V  
 HA12223F: V<sub>CC</sub> = 7.2V

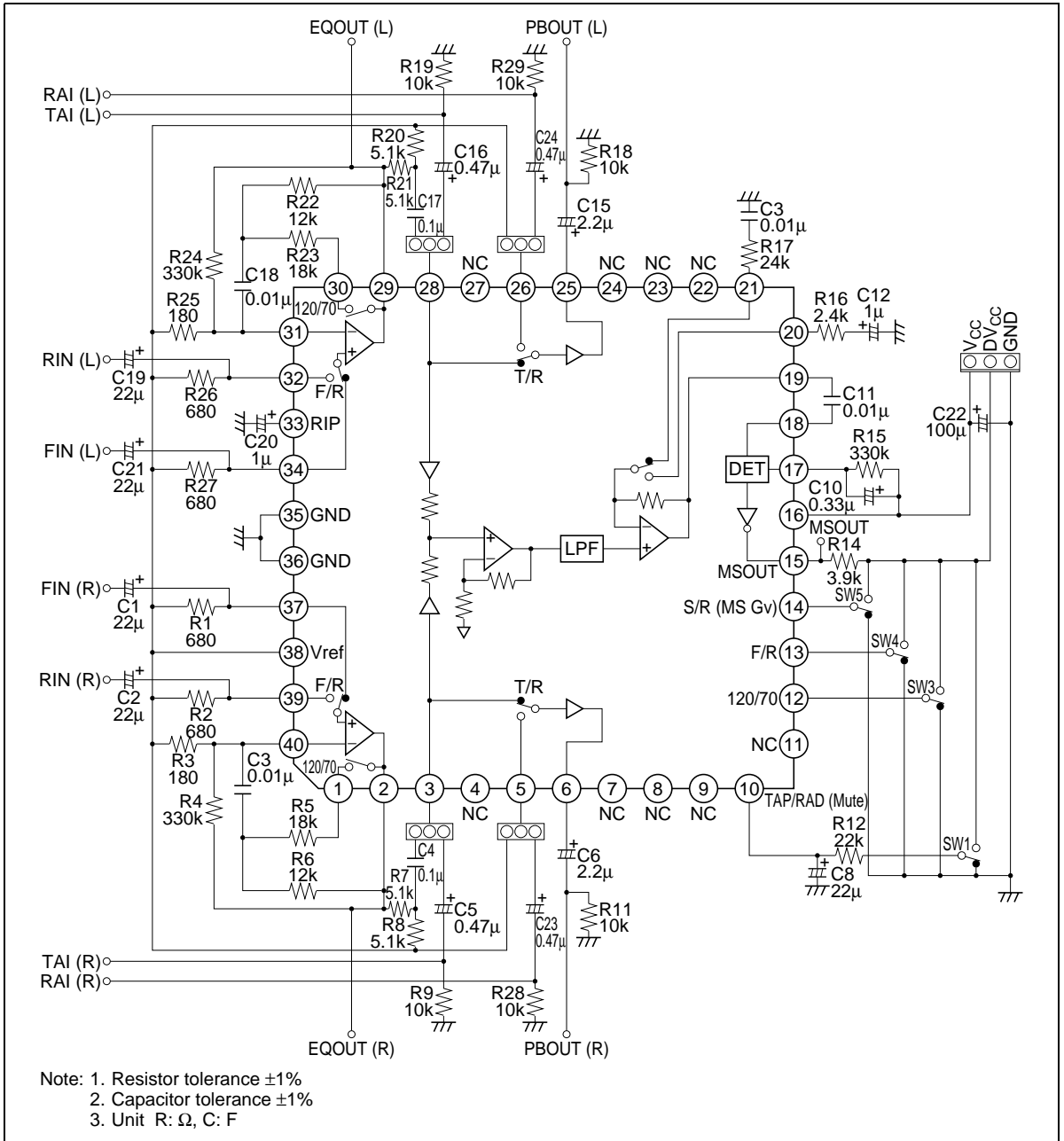
# HA12216F/HA12221F Series

## Test Circuit

### HA12216F Series

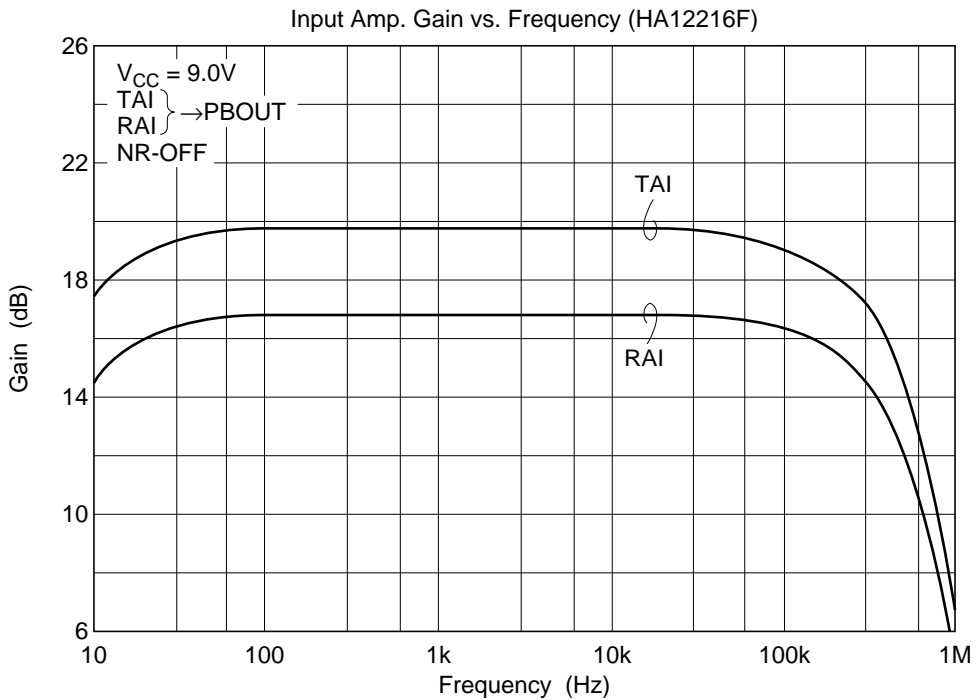
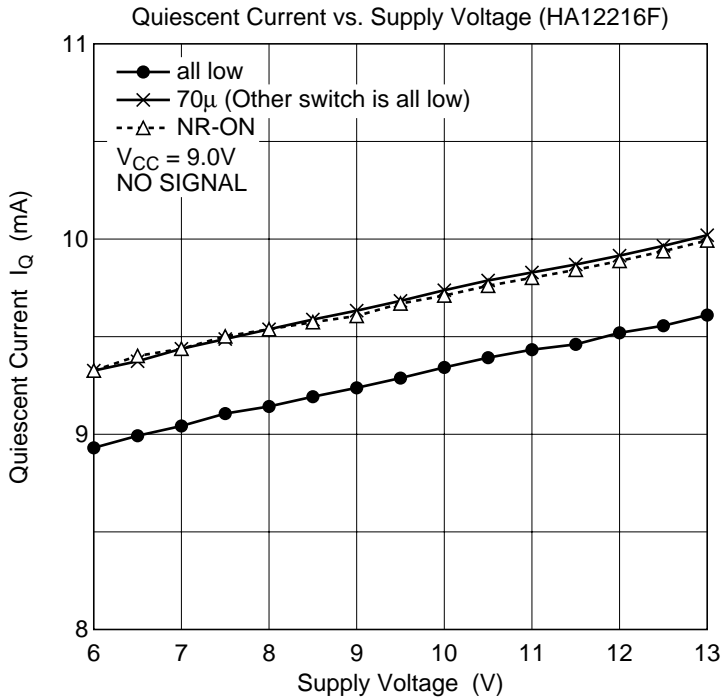


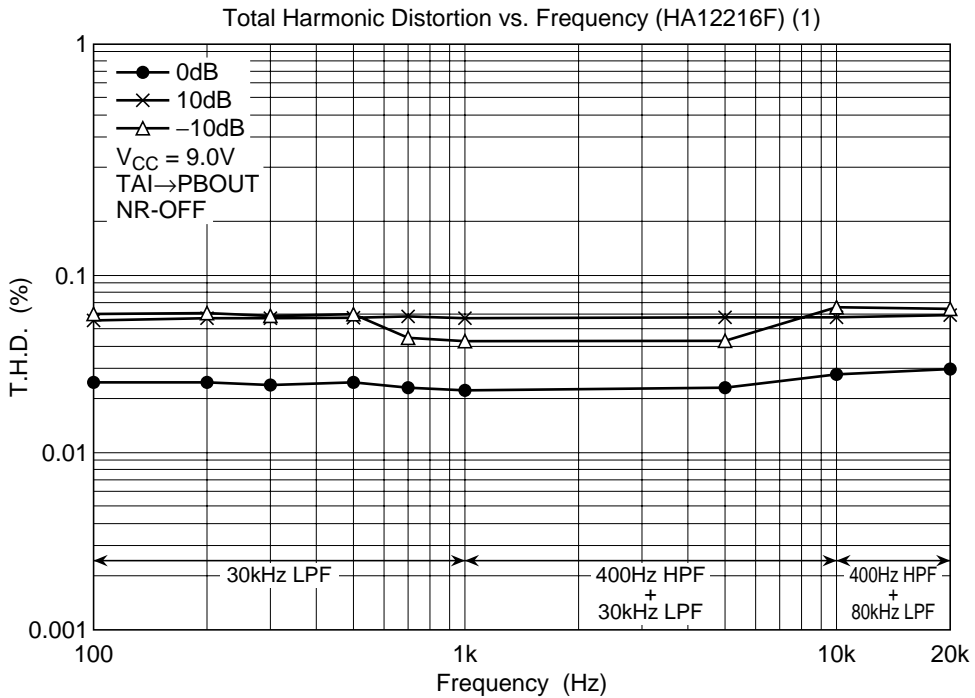
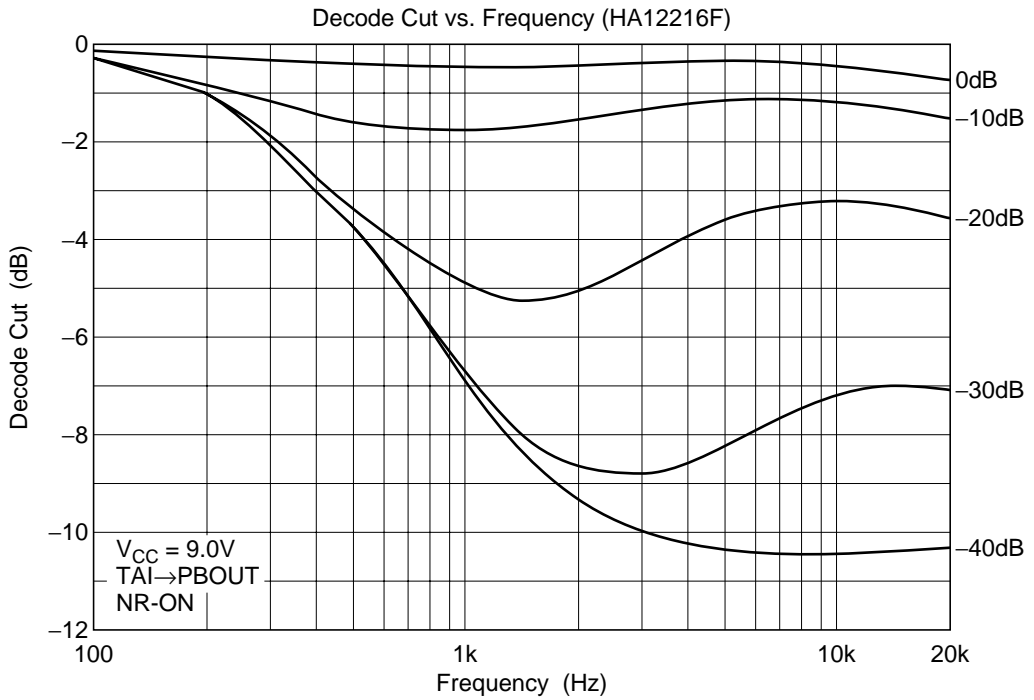
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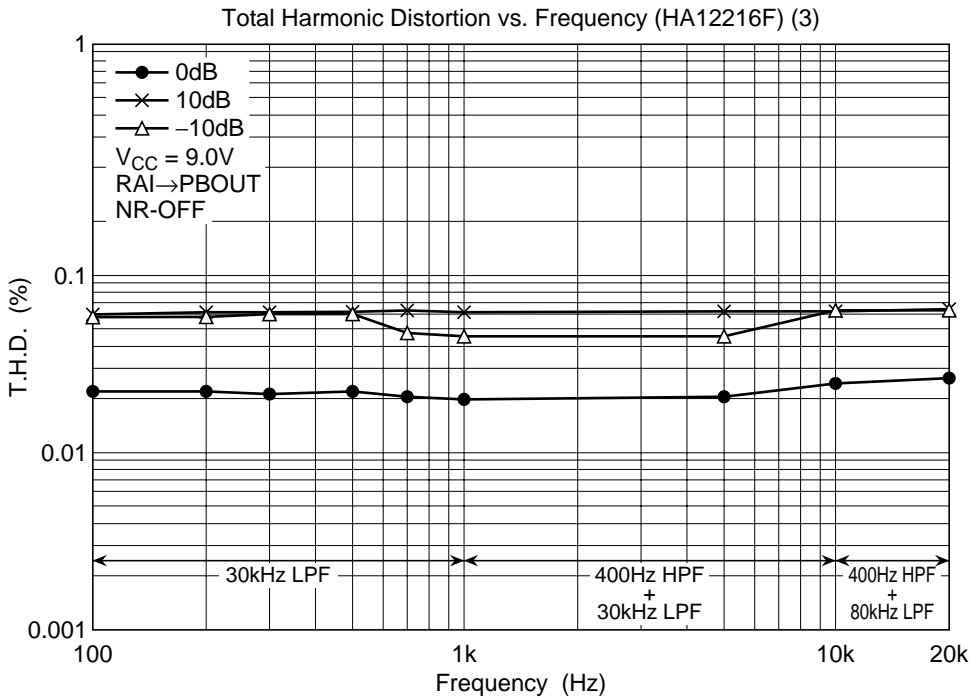
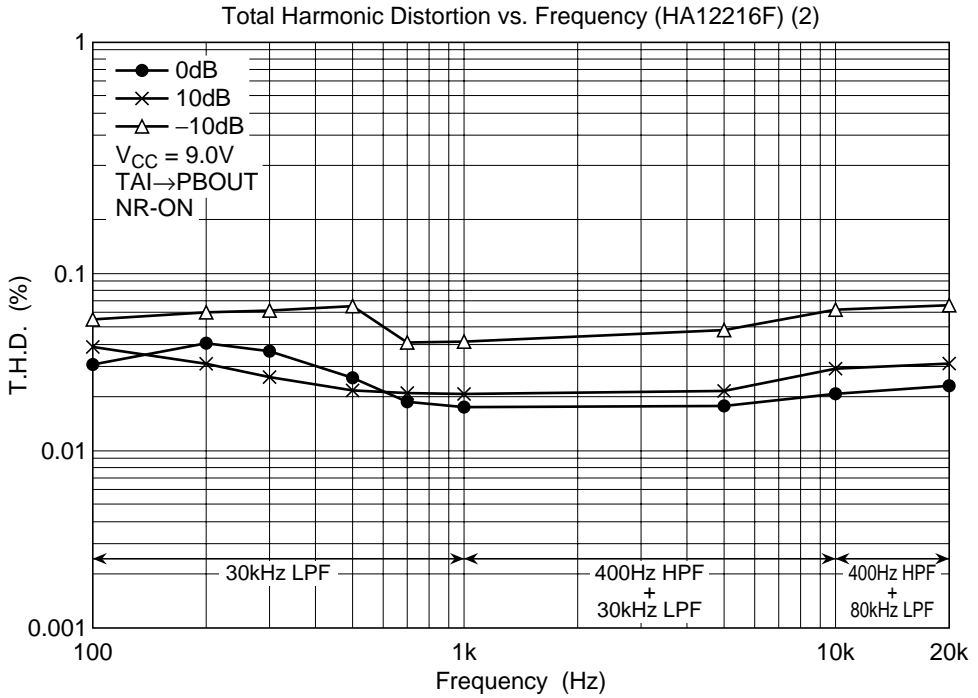
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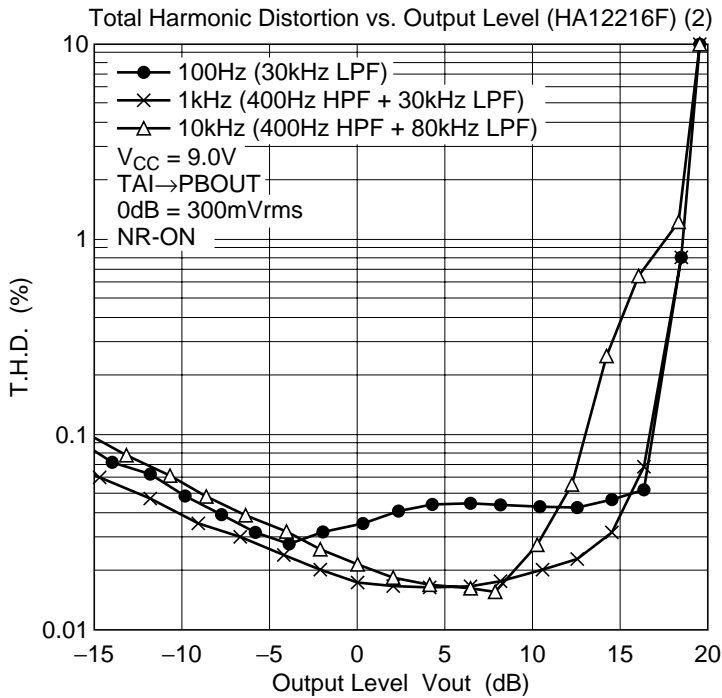
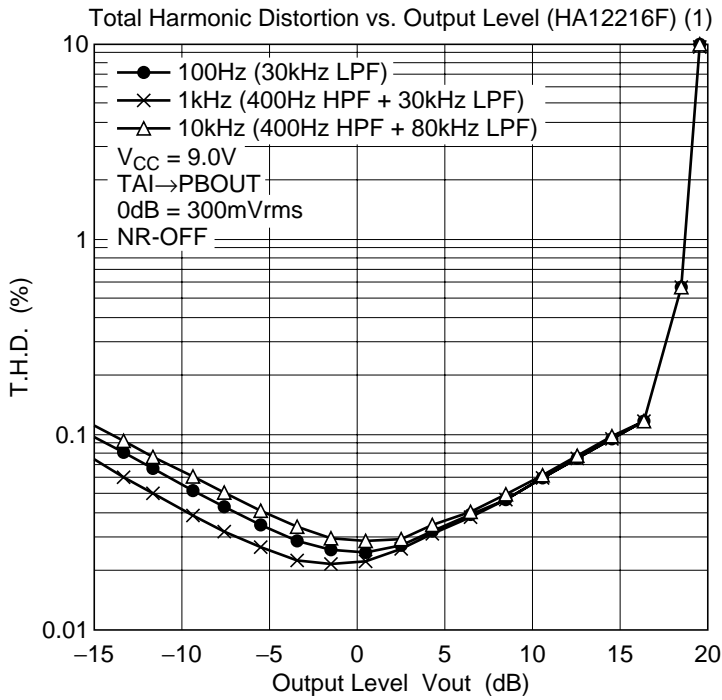
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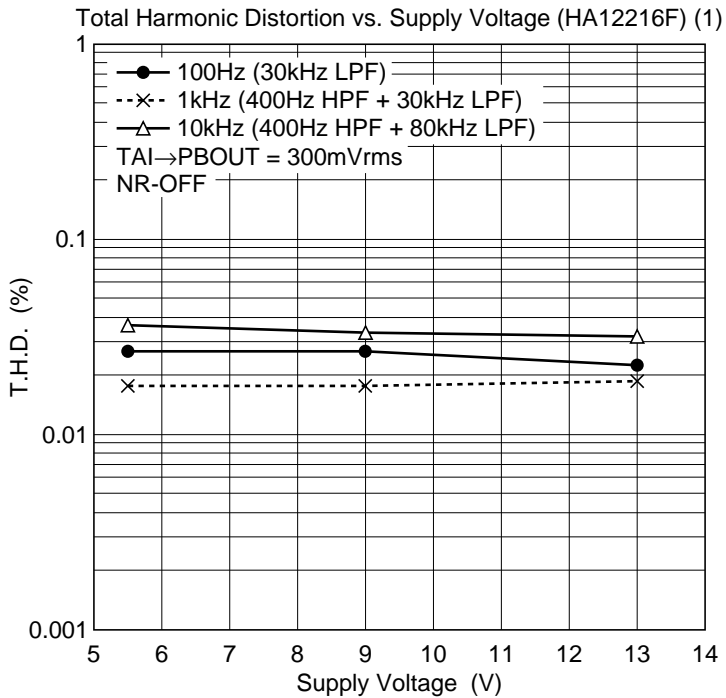
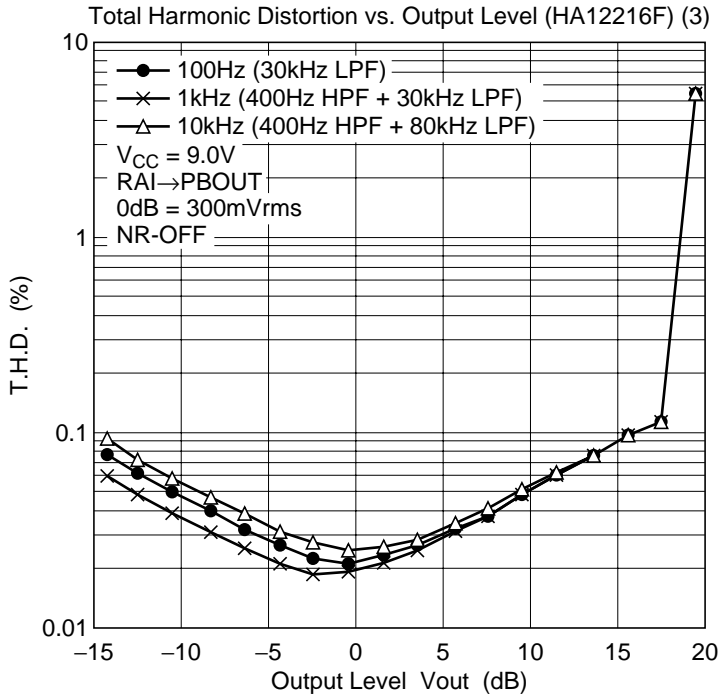


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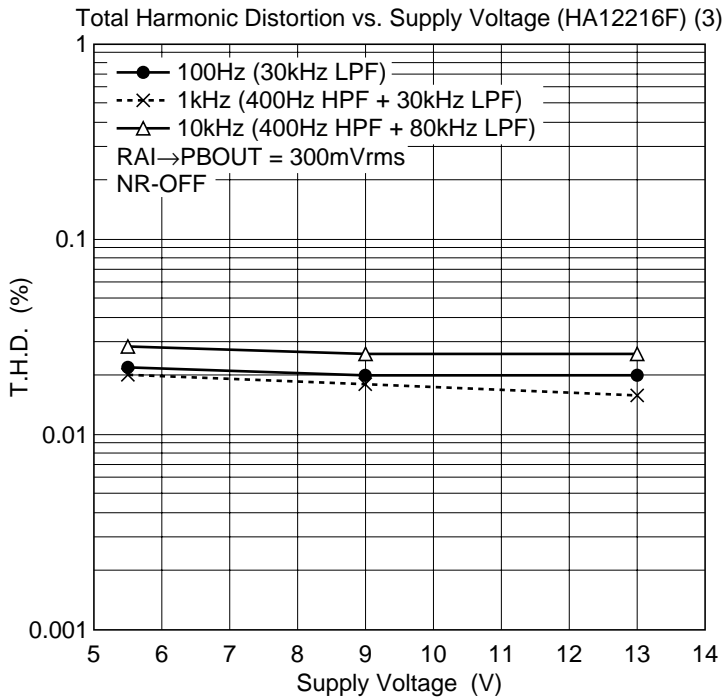
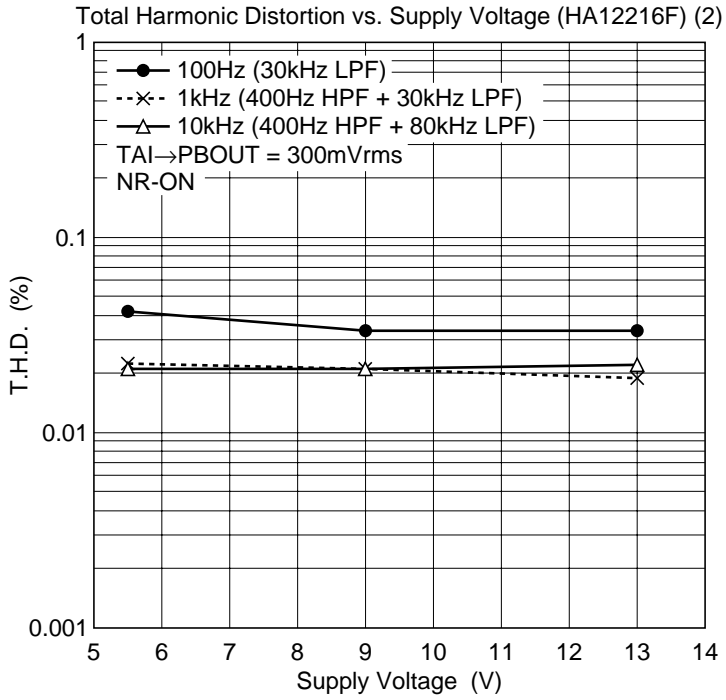




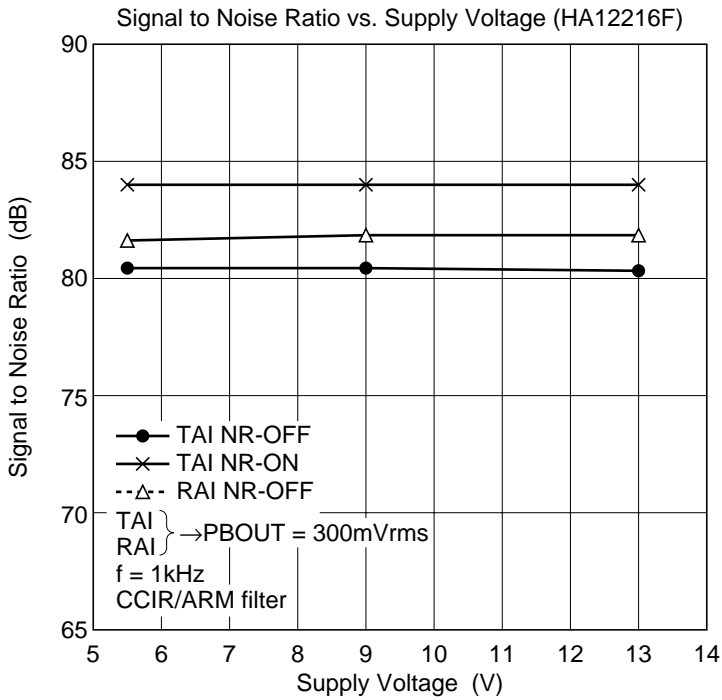
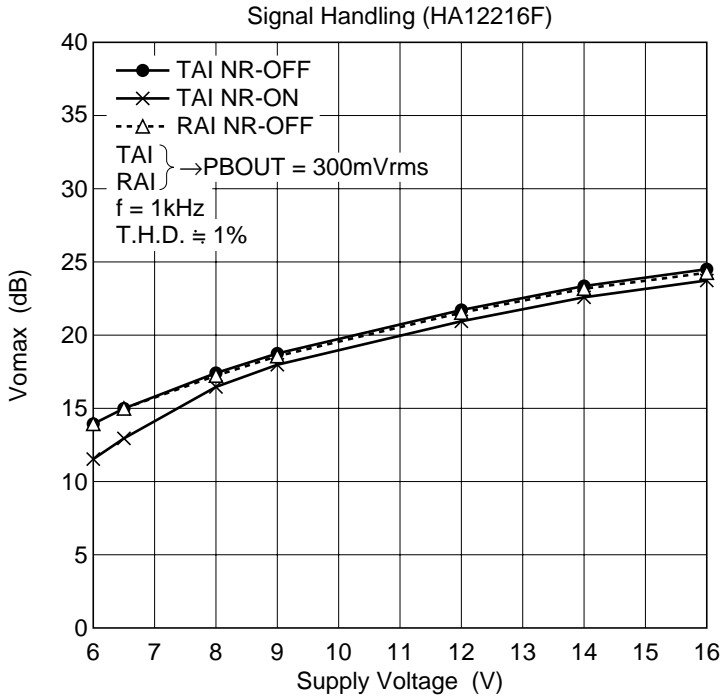
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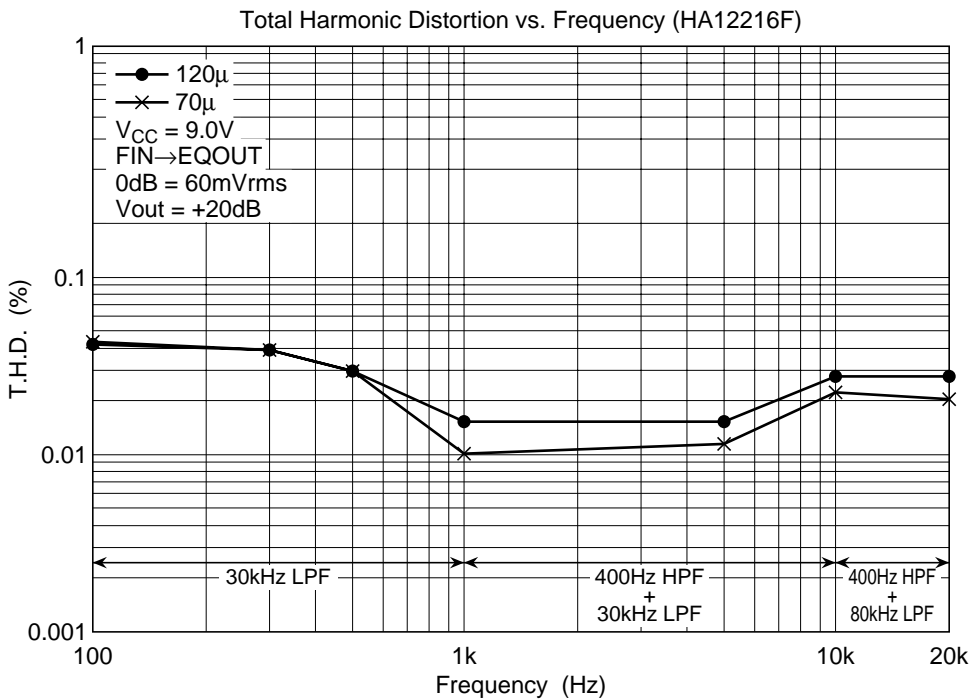
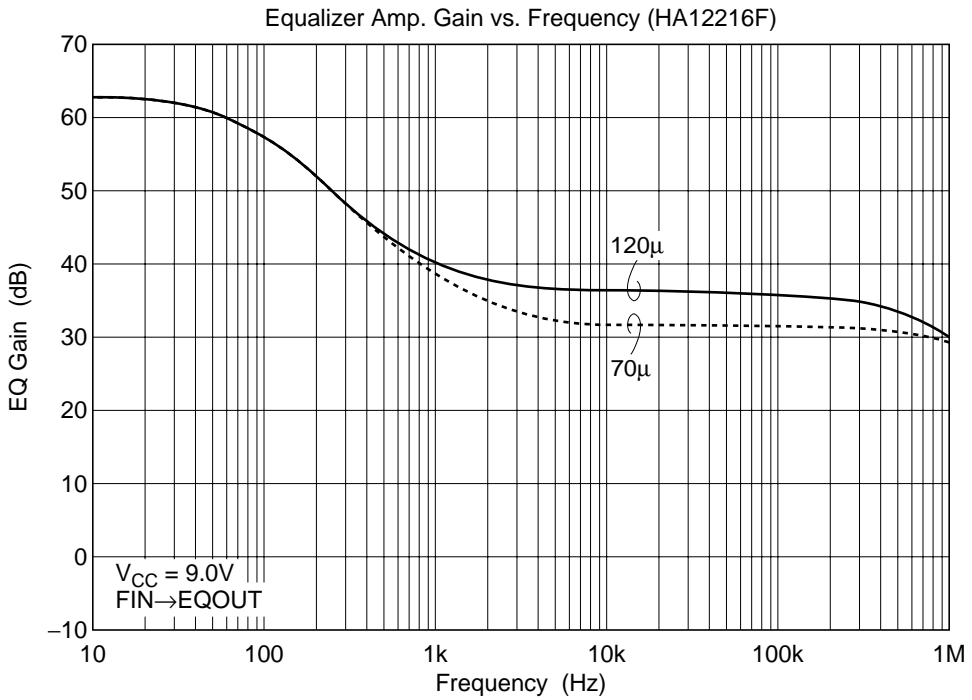




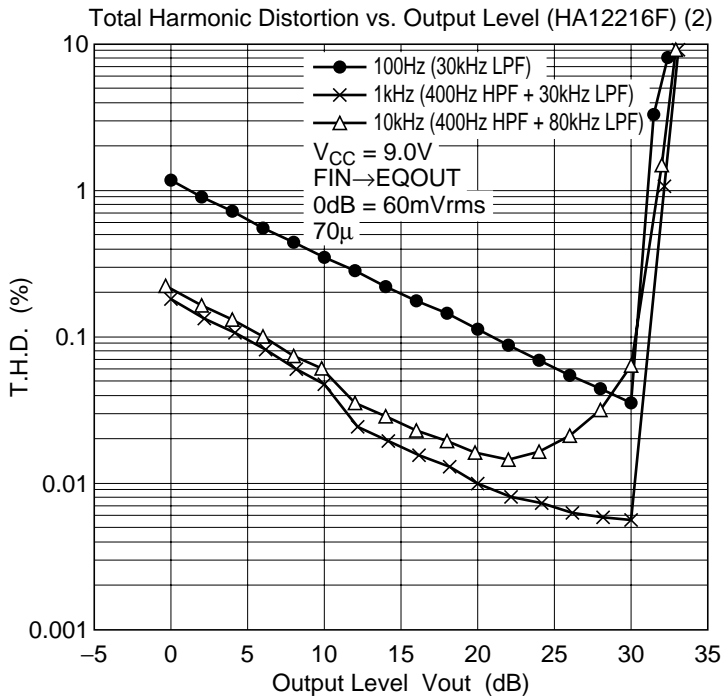
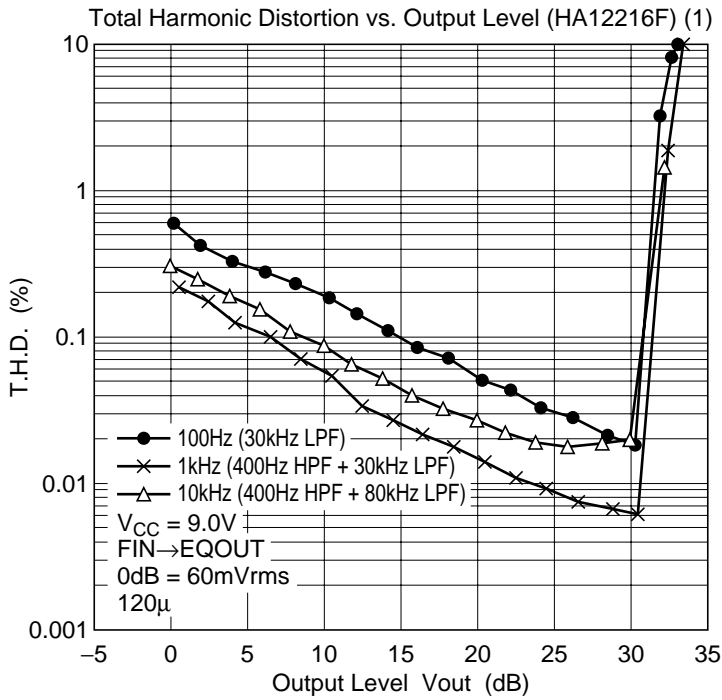


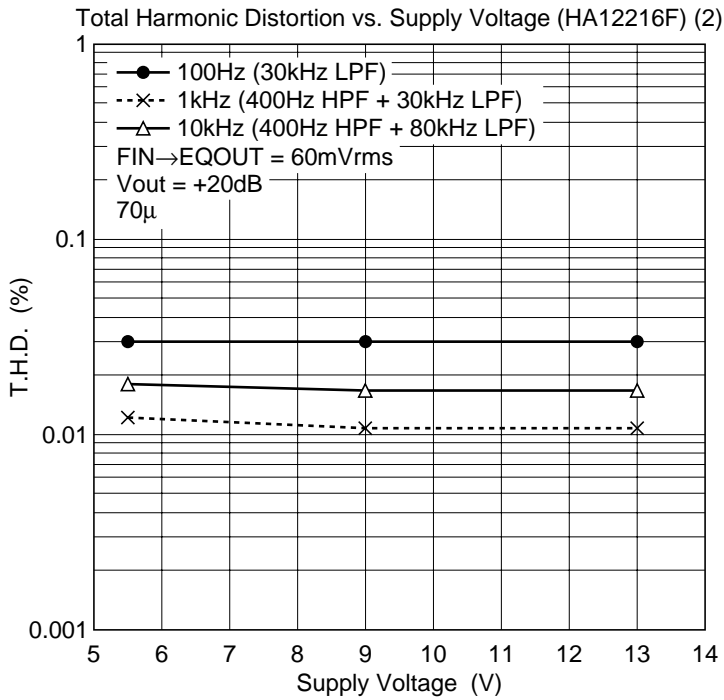
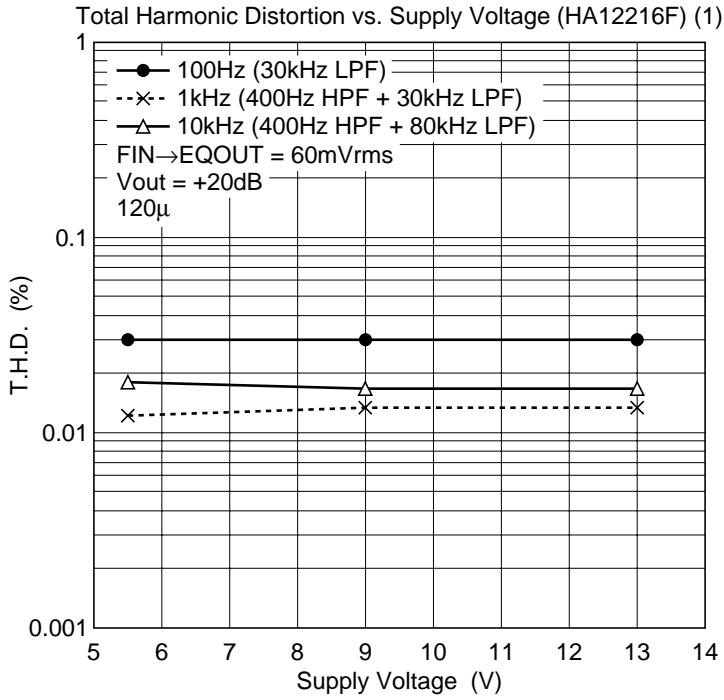
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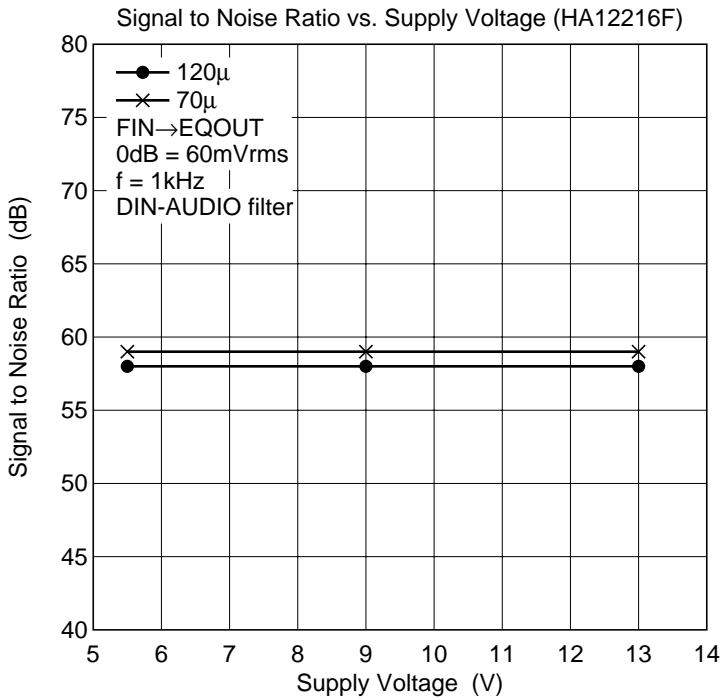
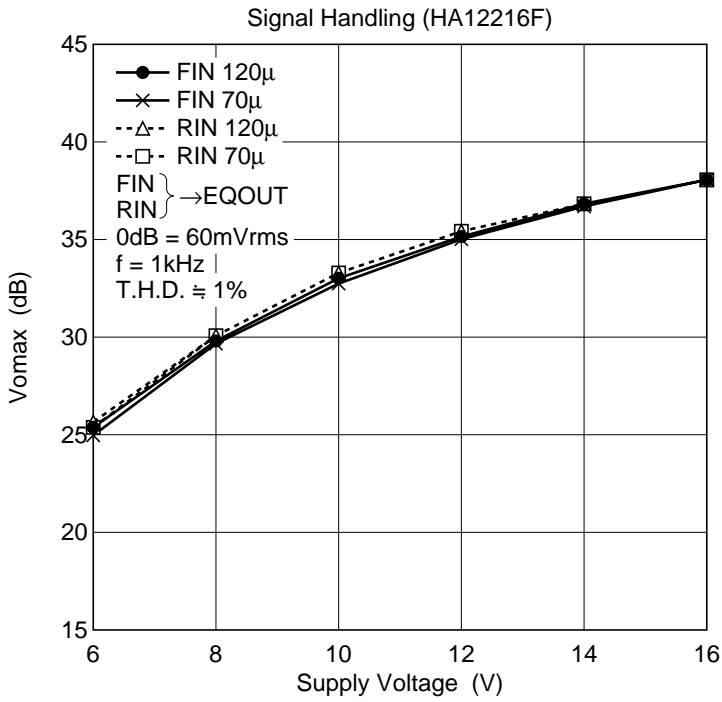


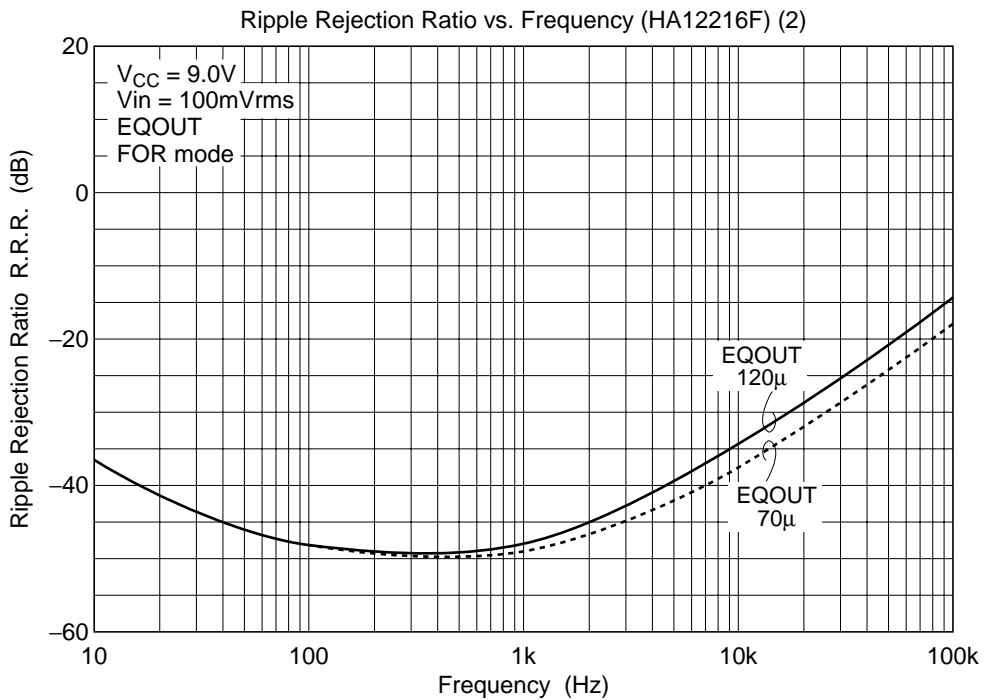
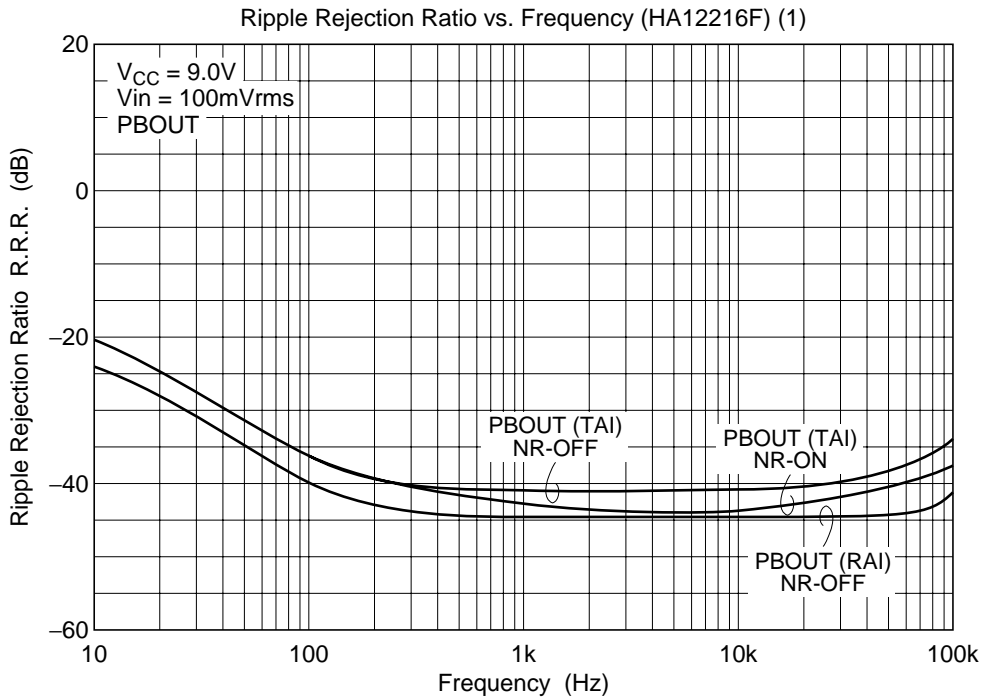
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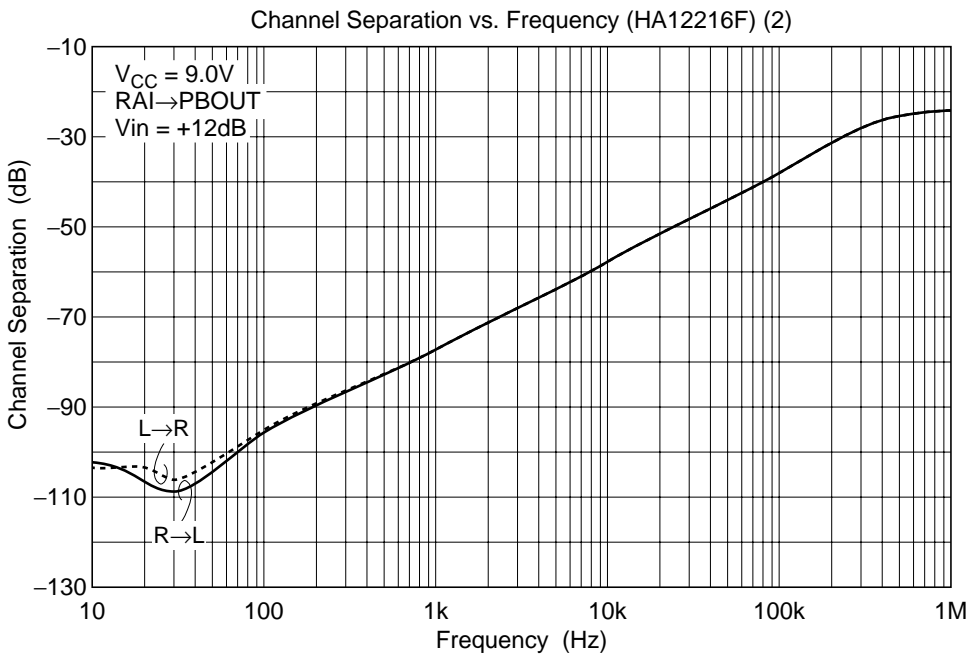
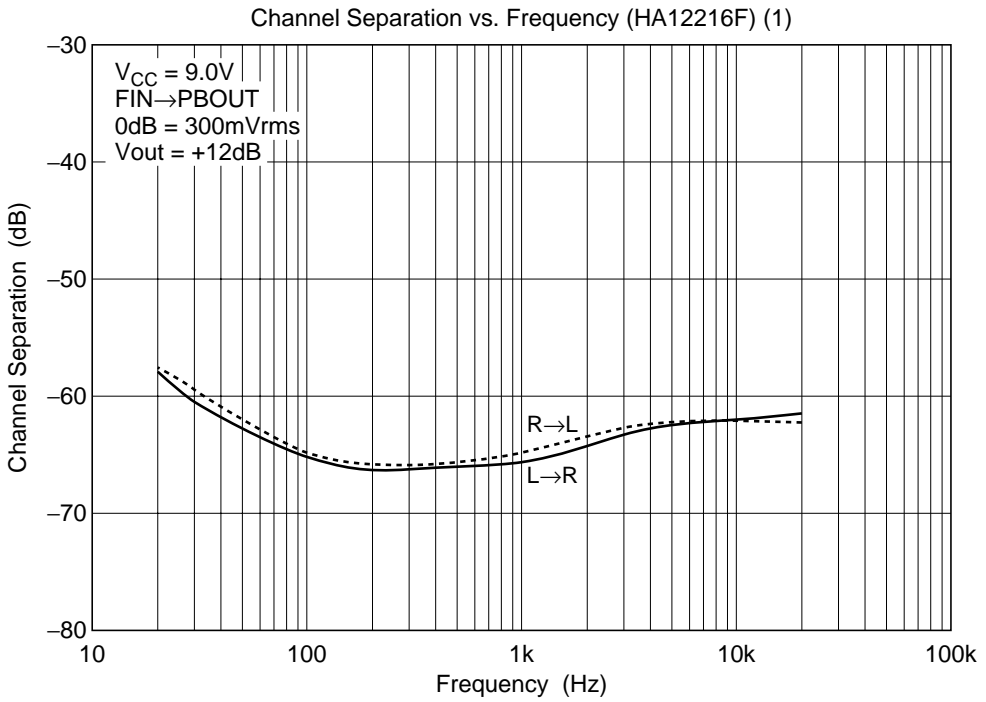


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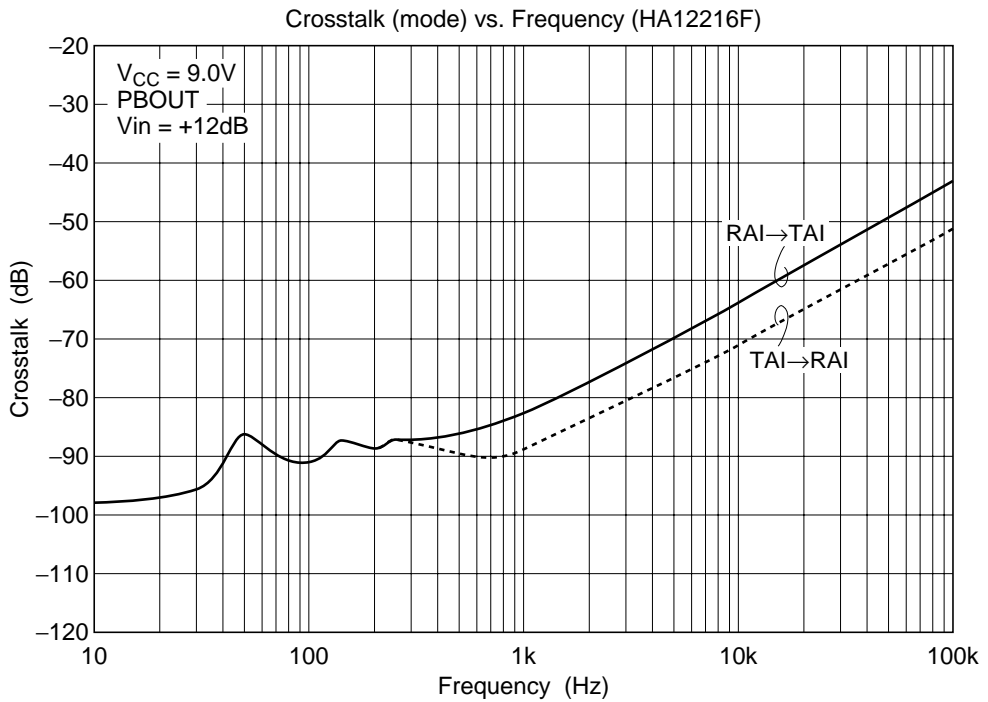
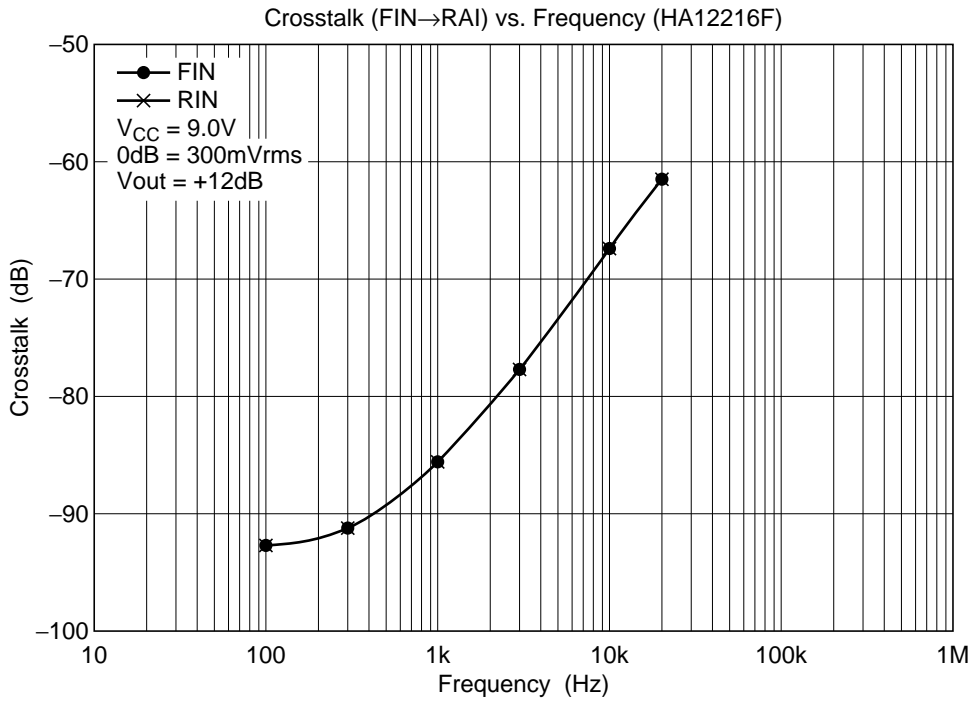




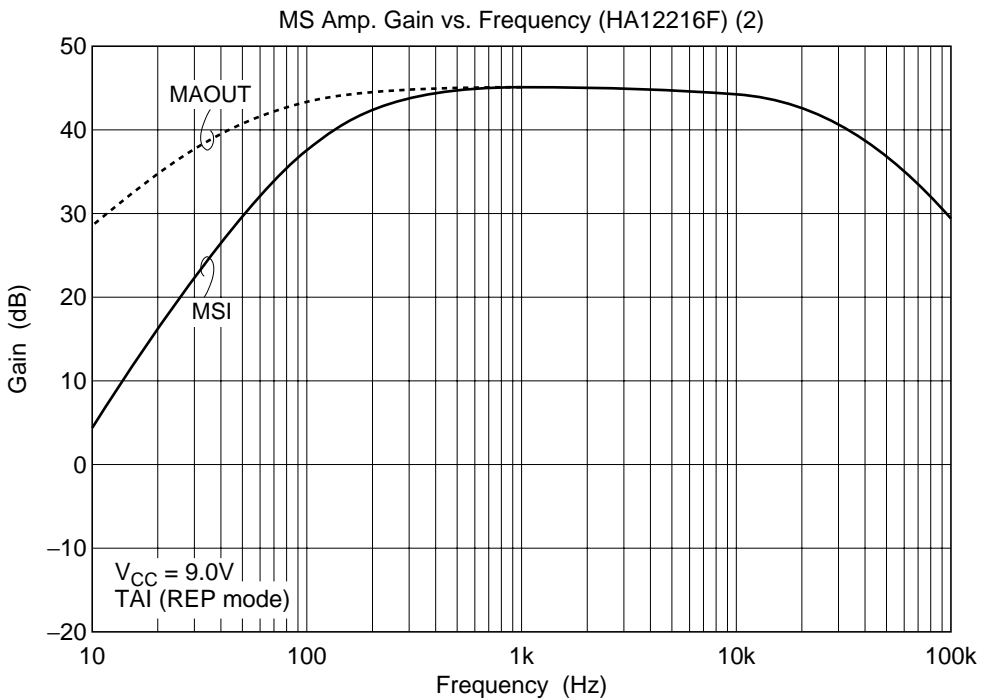
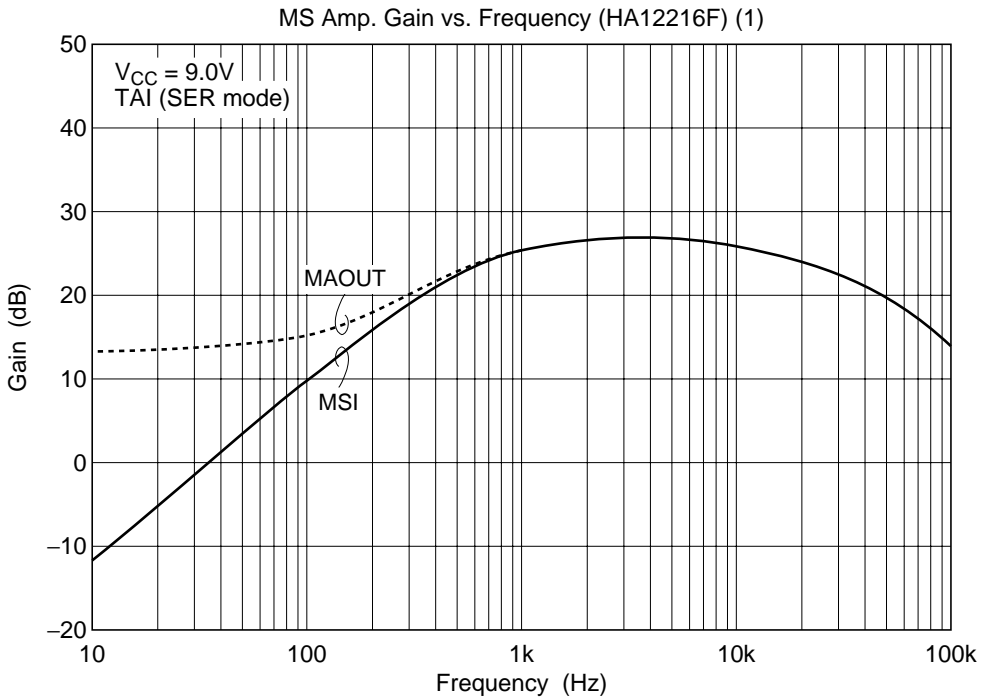
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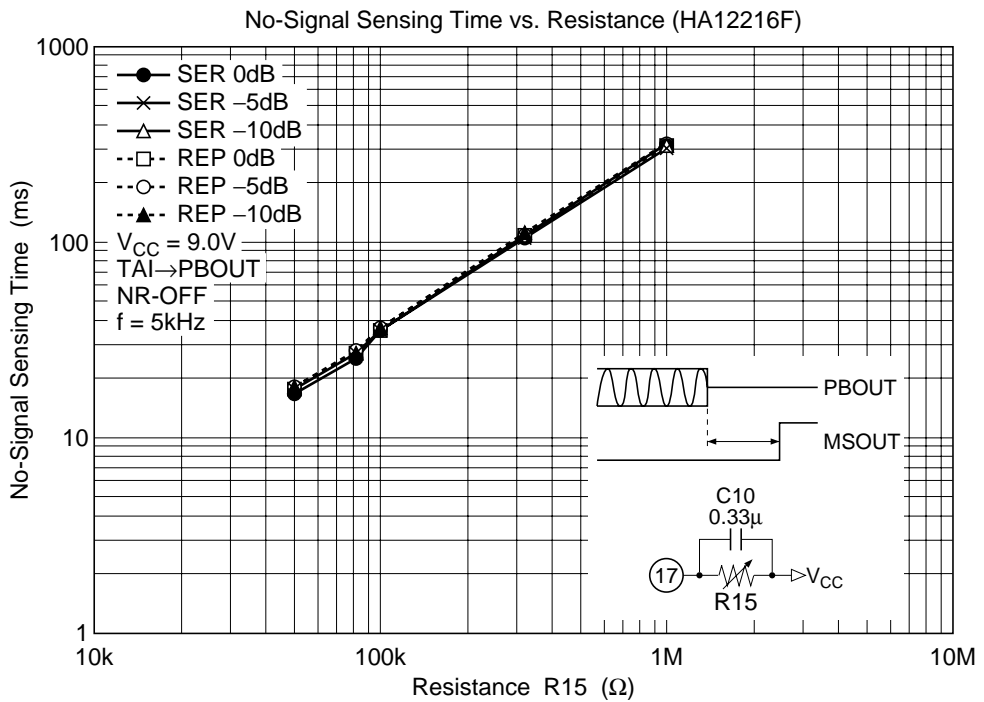
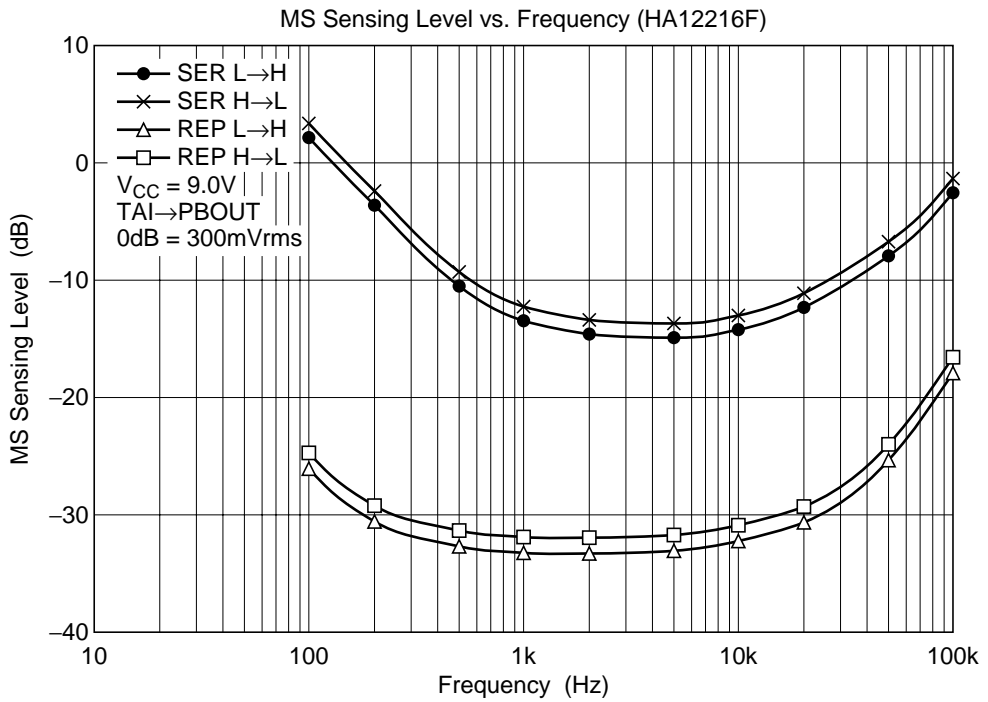




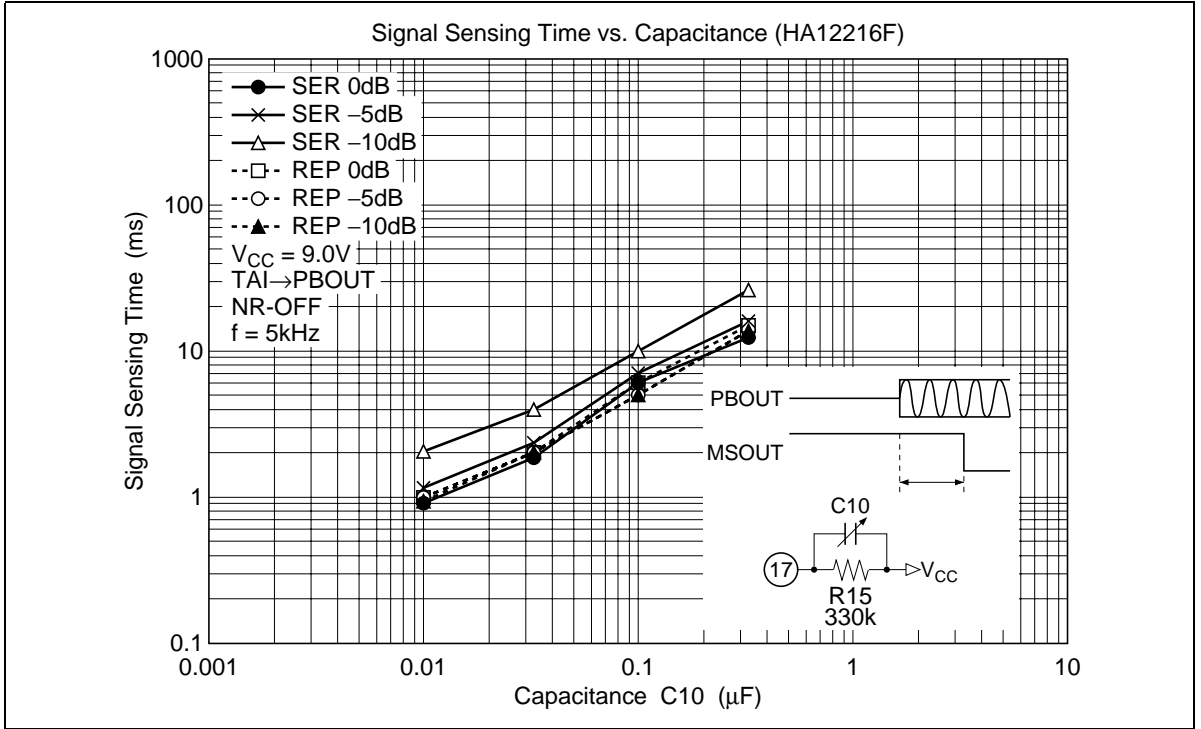


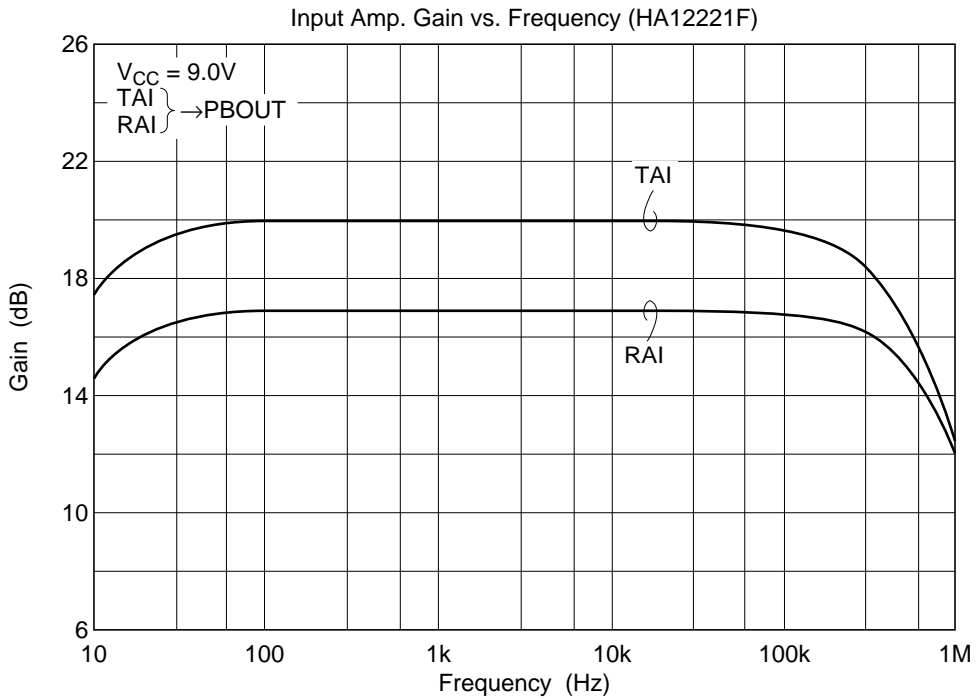
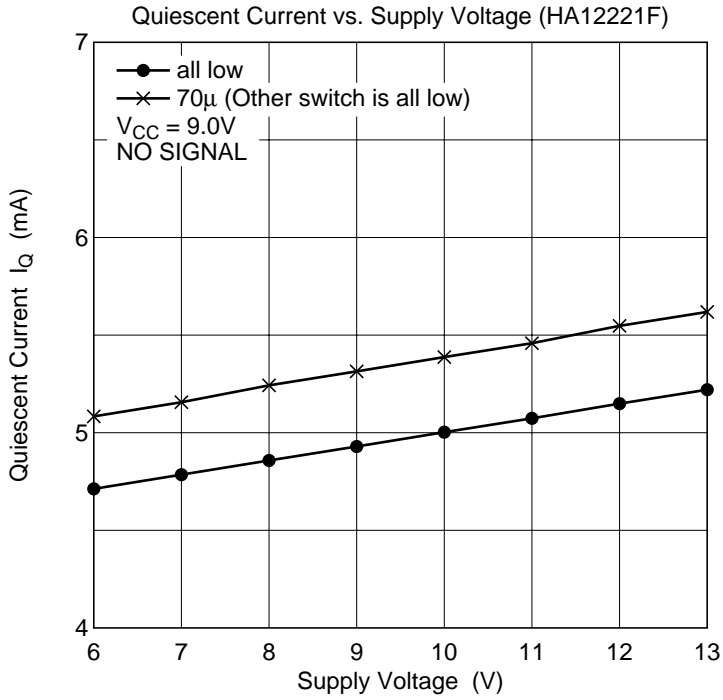
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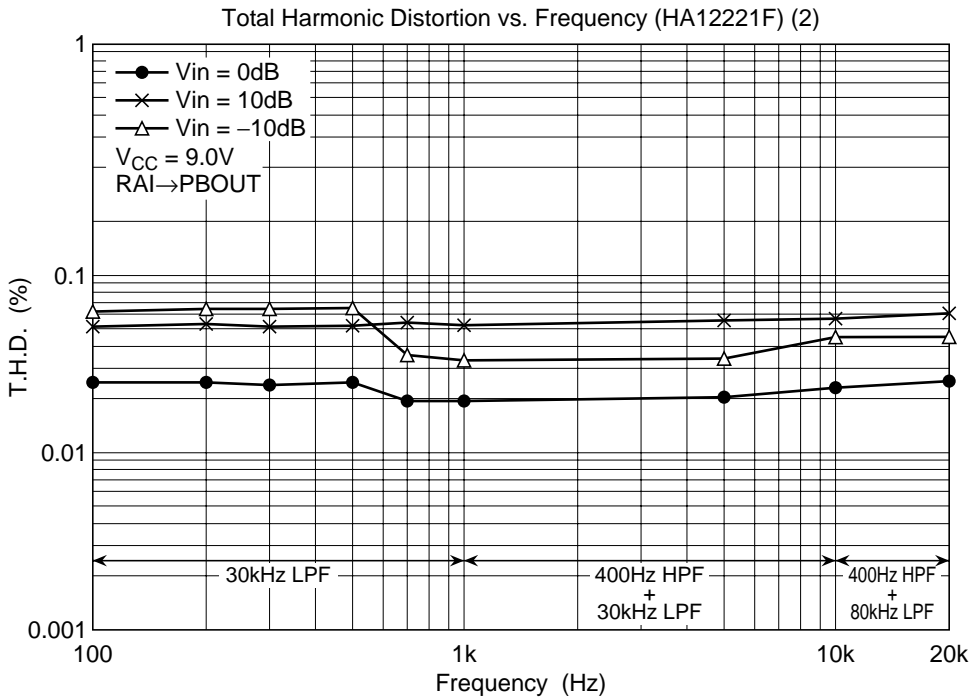
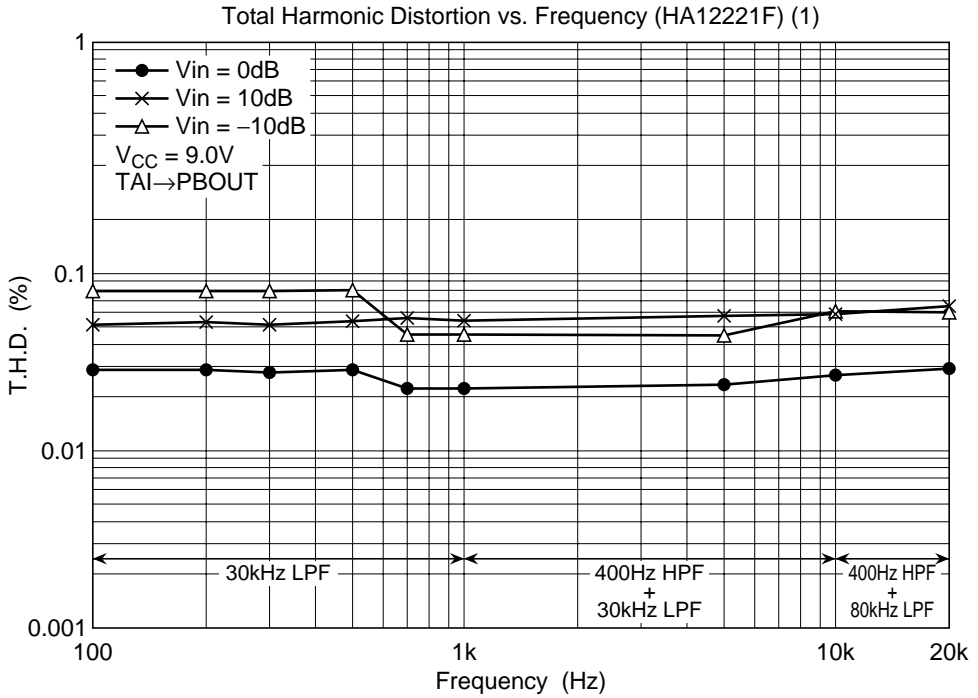


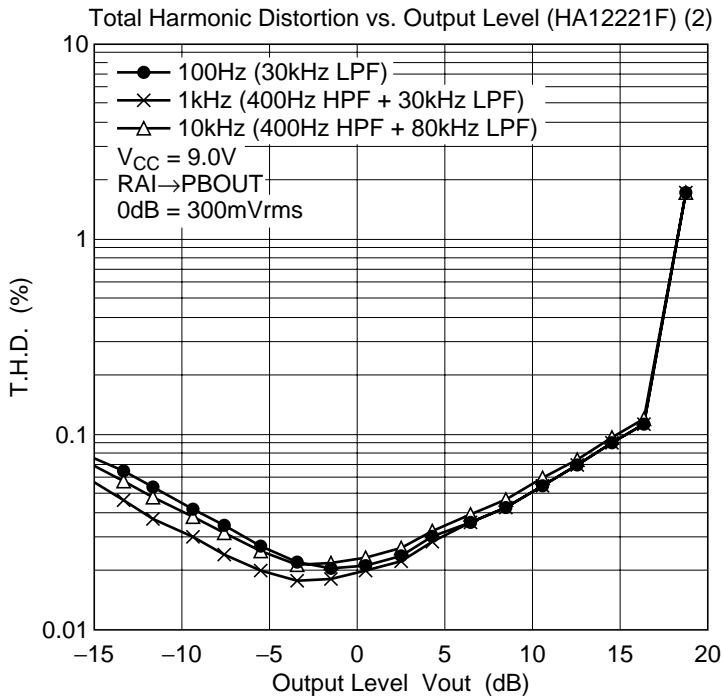
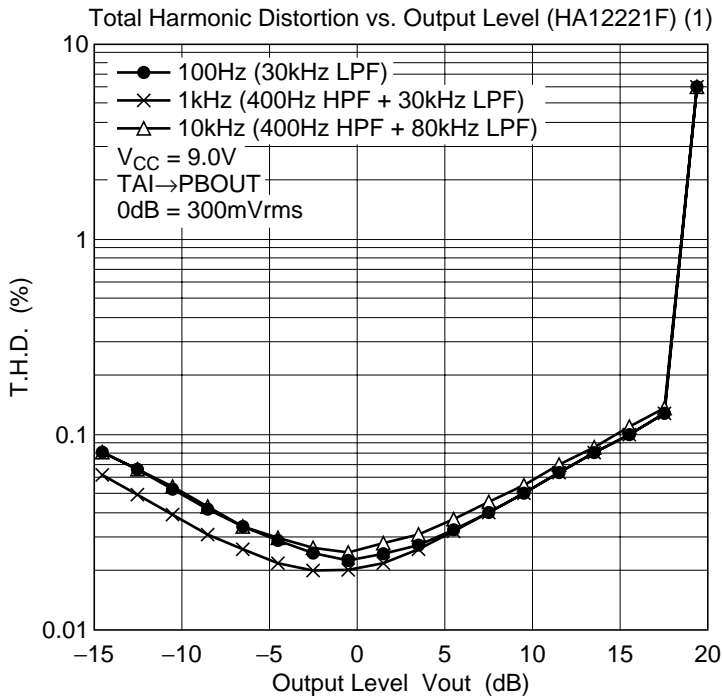
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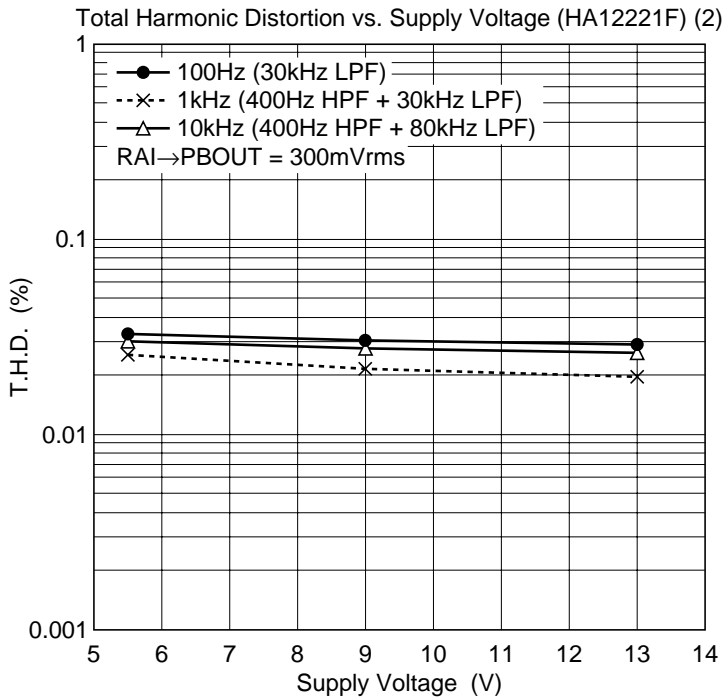
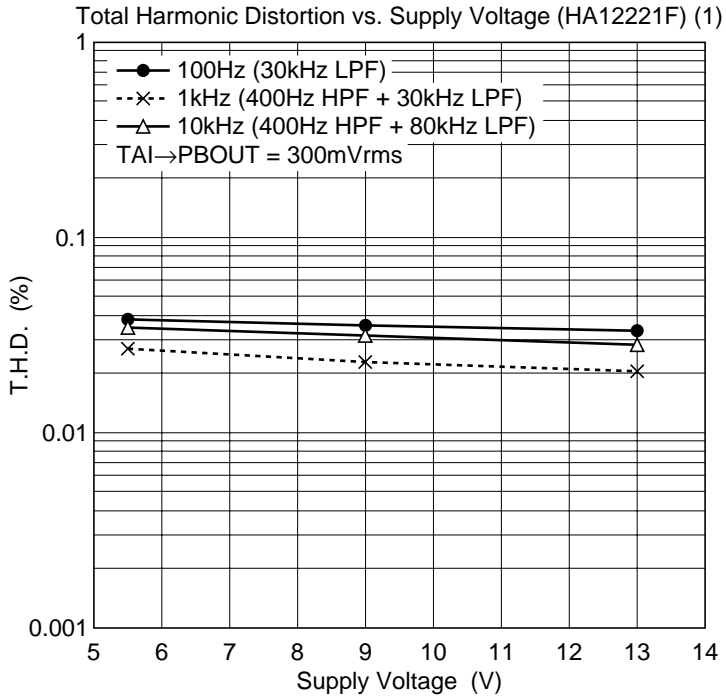


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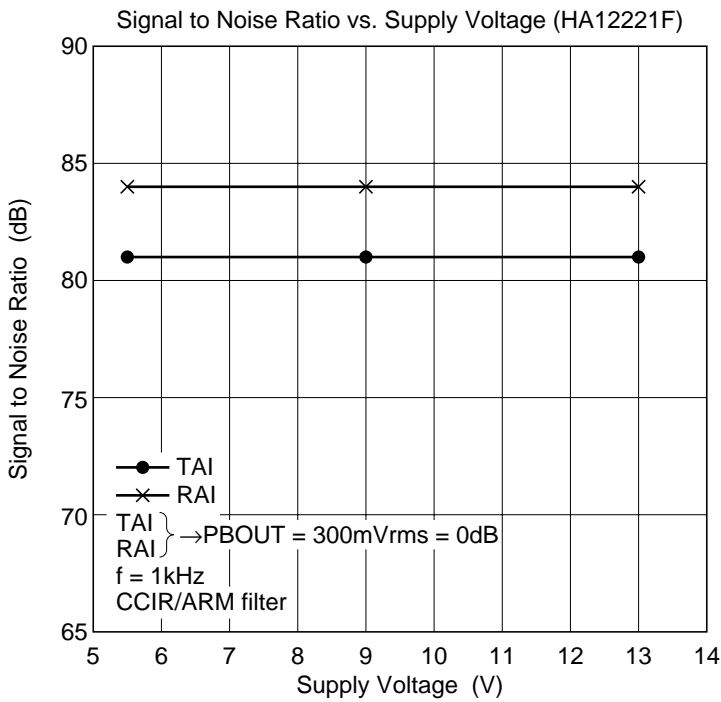
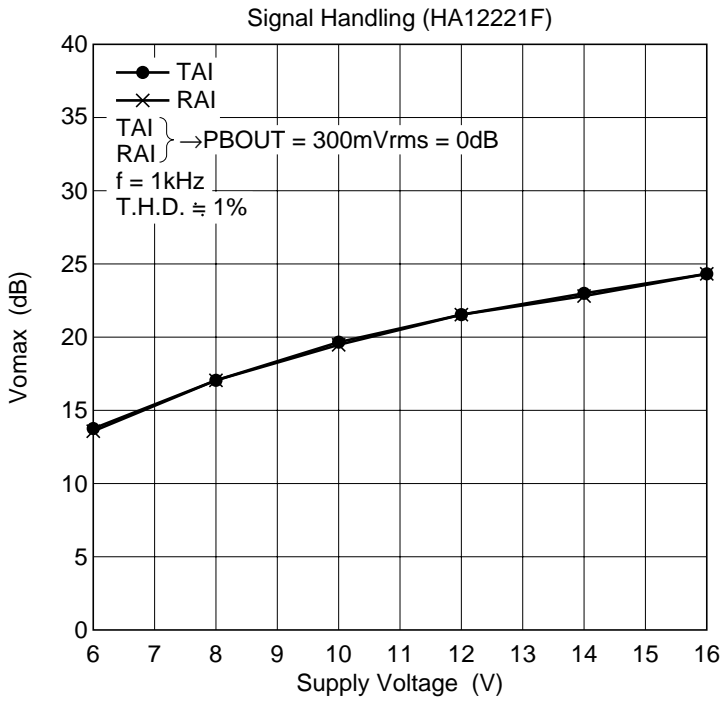




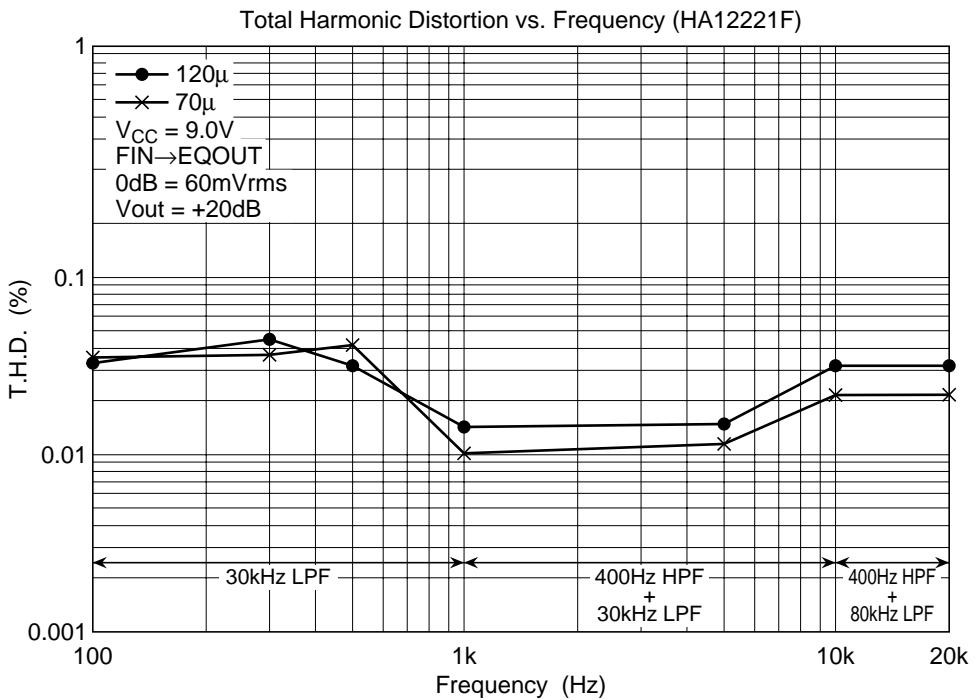
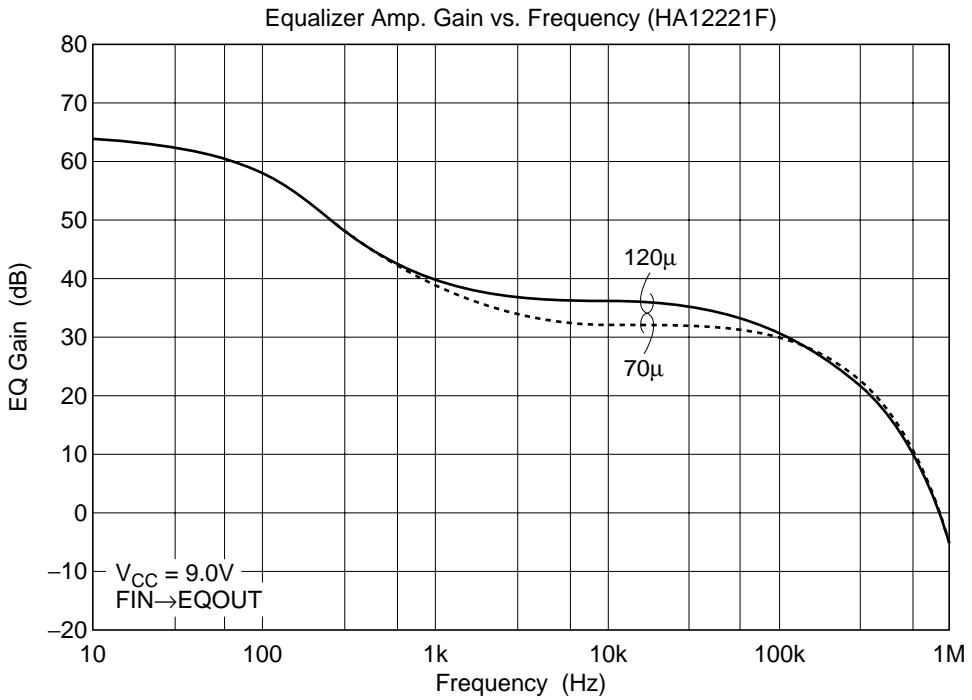
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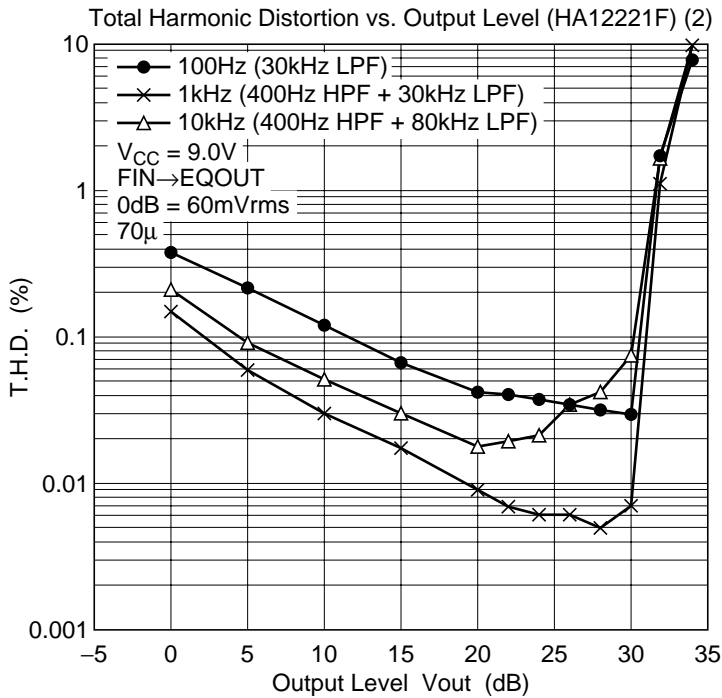
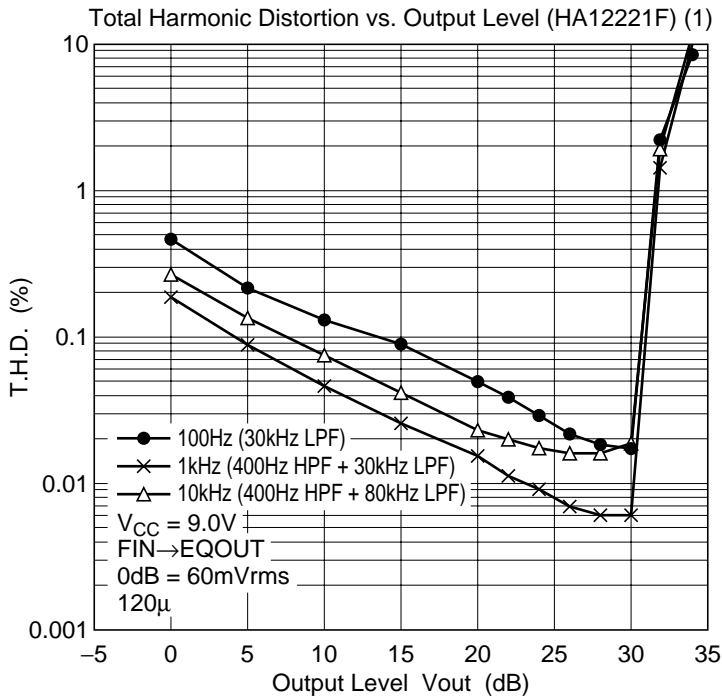




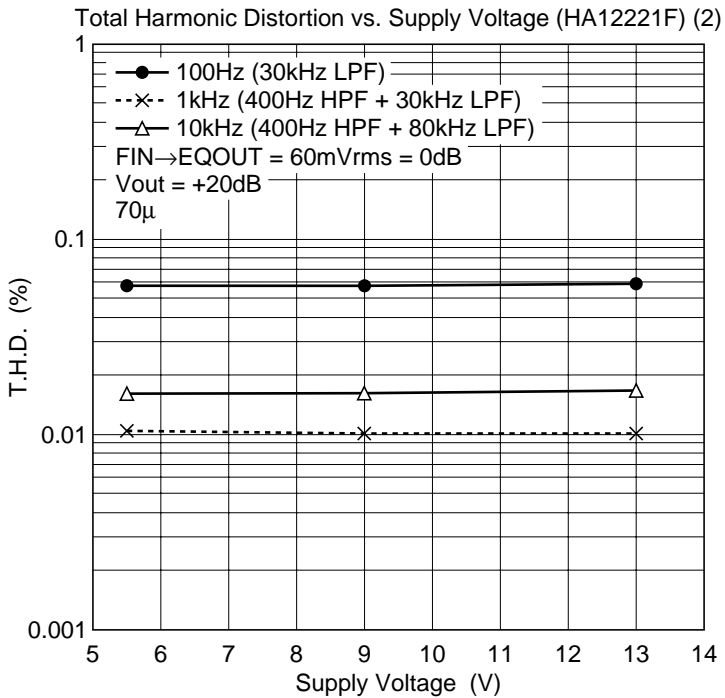
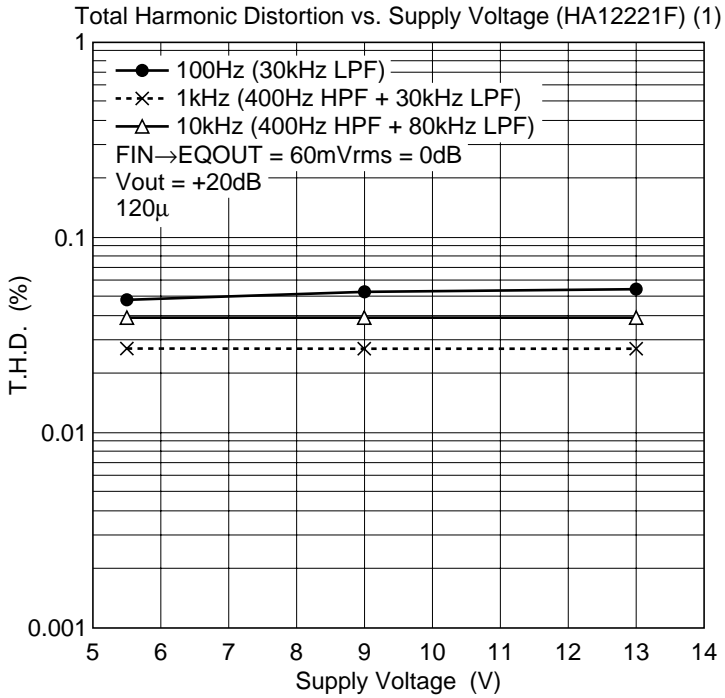


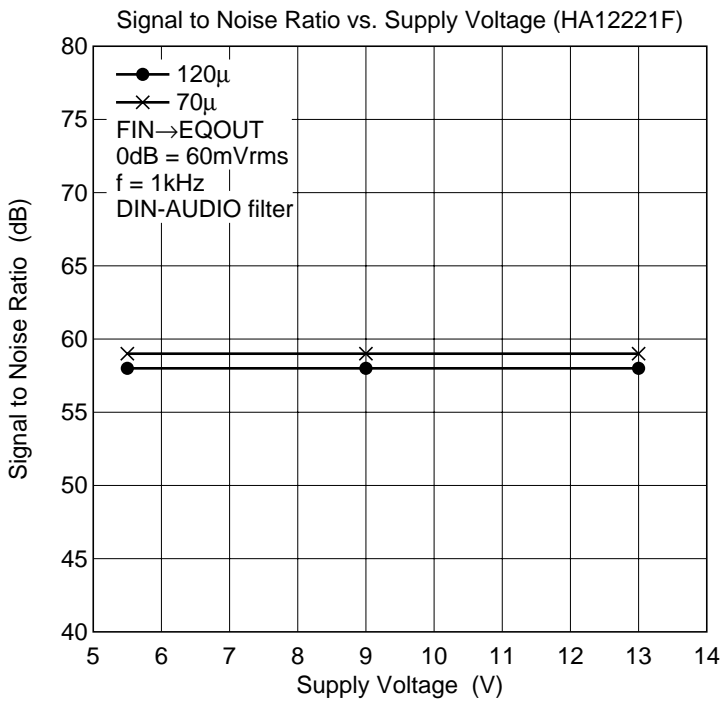
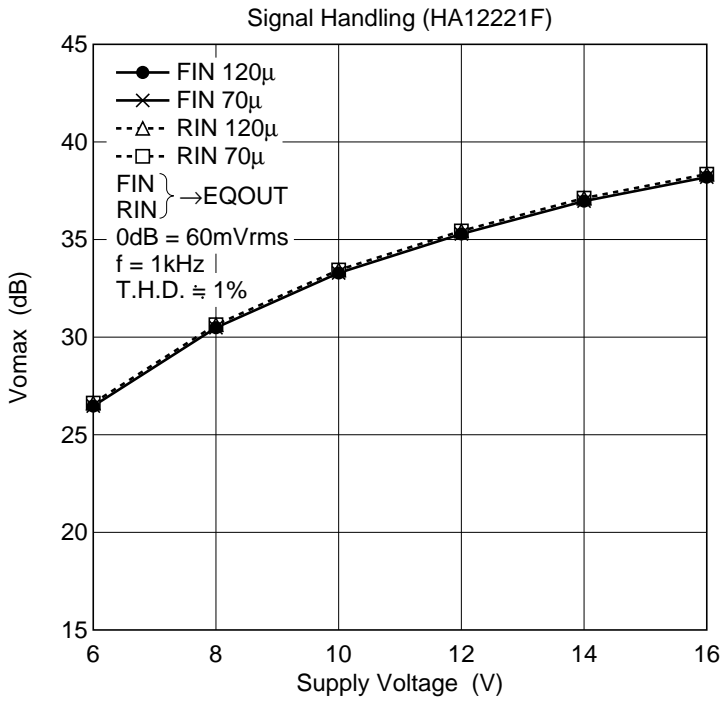
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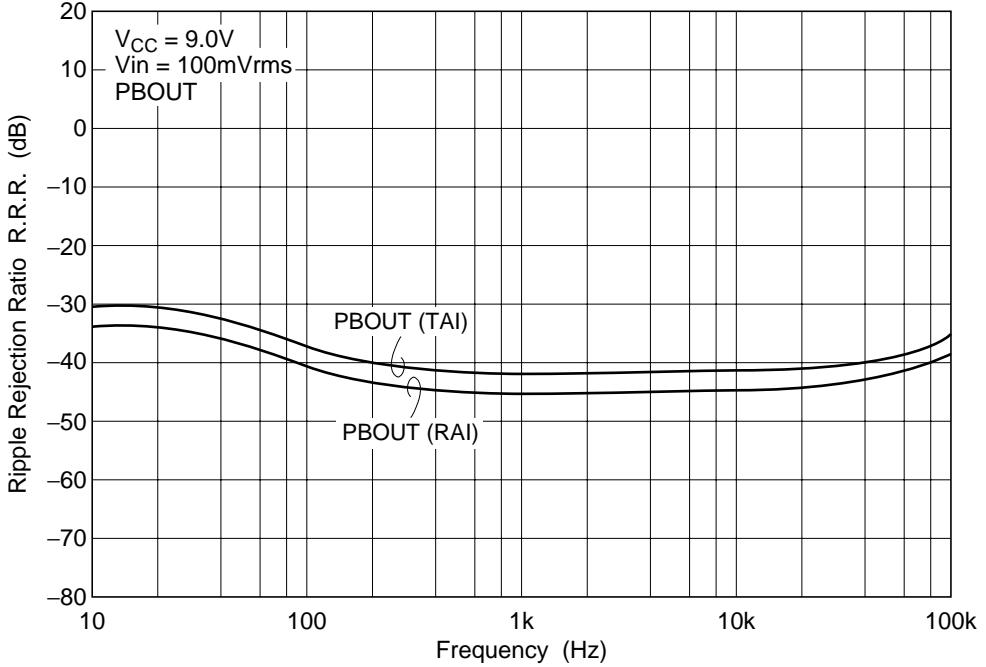
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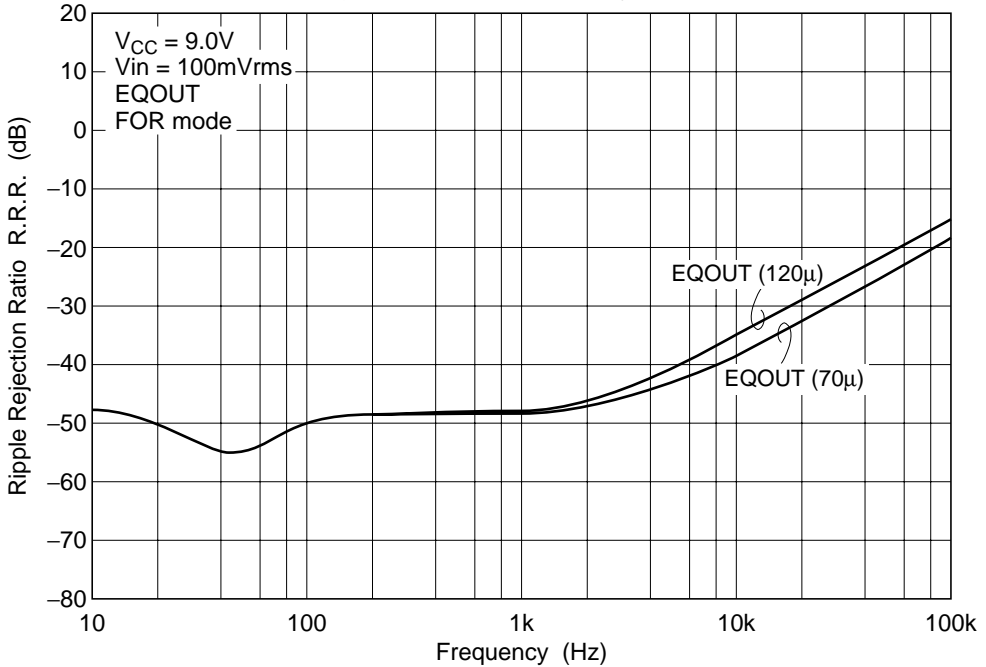


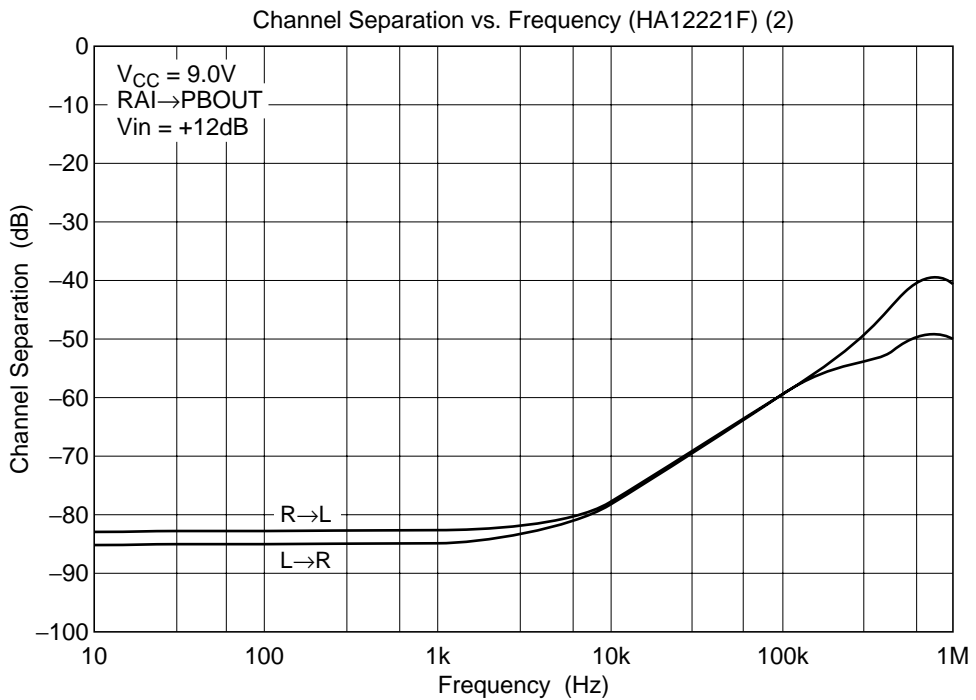
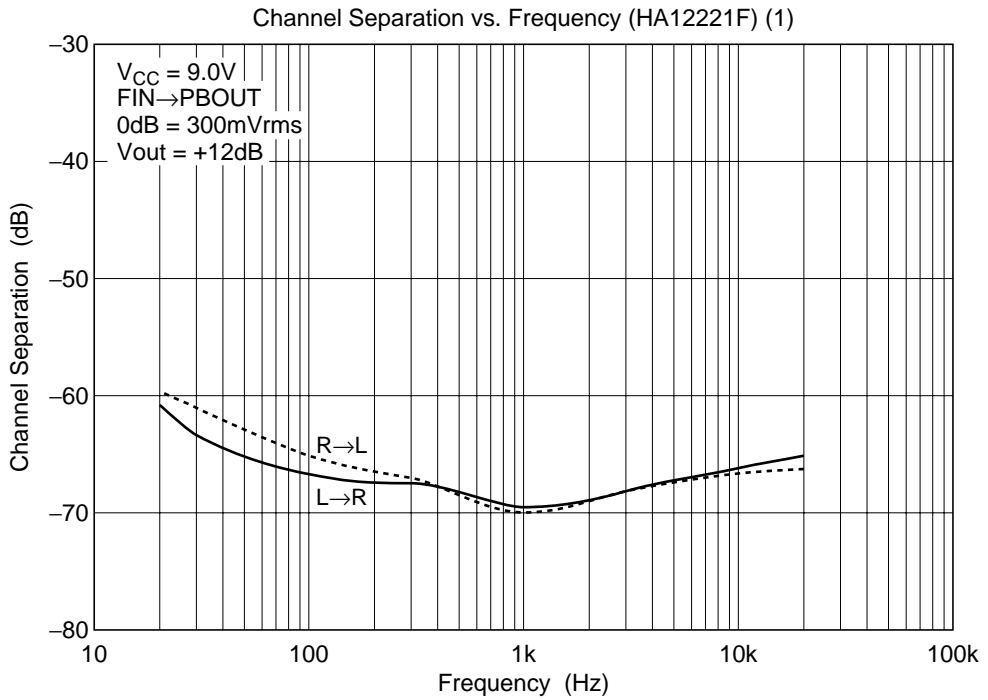
# HA12216F/HA12221F Series

Ripple Rejection Ratio vs. Frequency (HA12221F) (1)

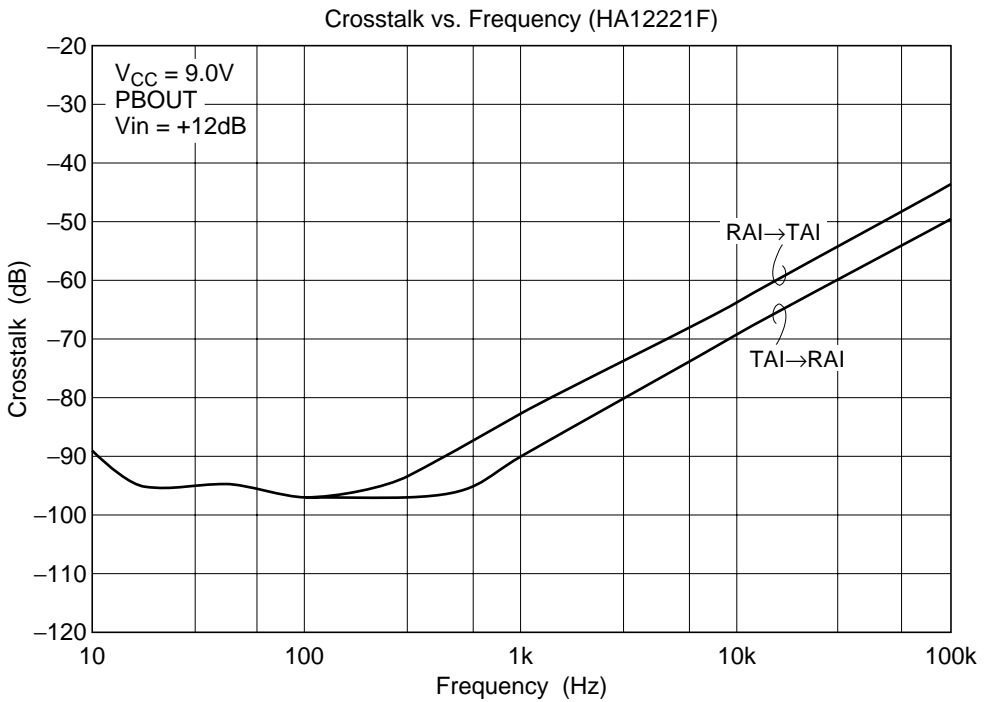
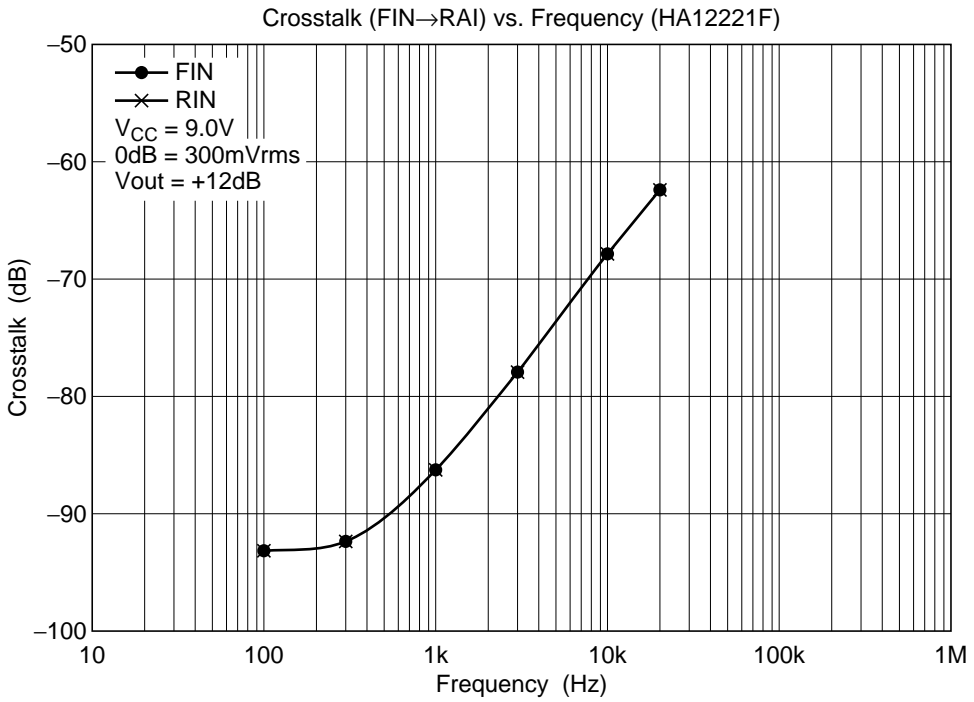


Ripple Rejection Ratio vs. Frequency (HA12221F) (2)



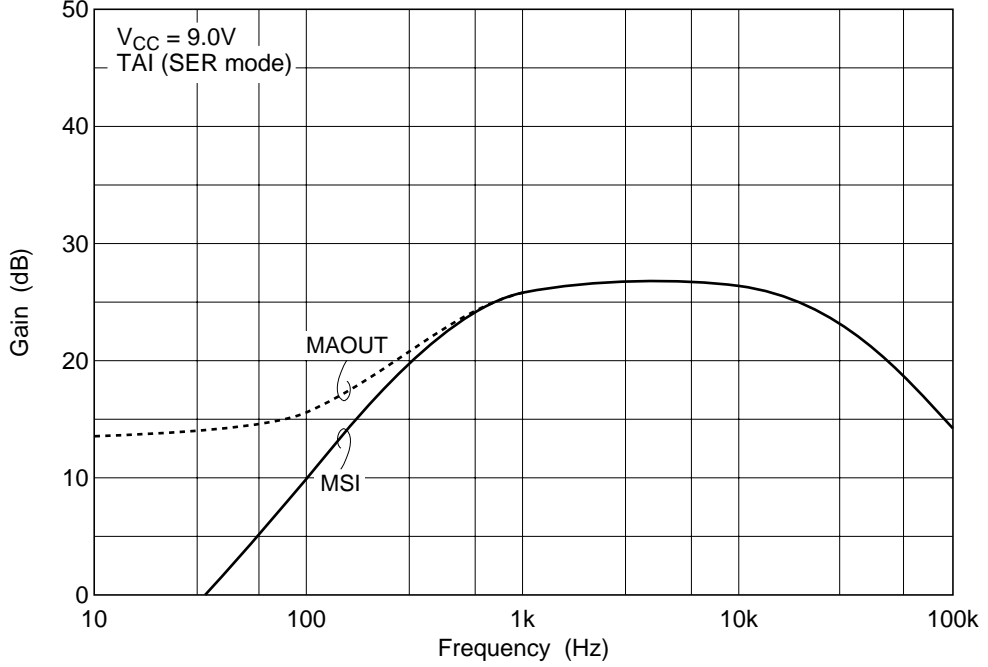


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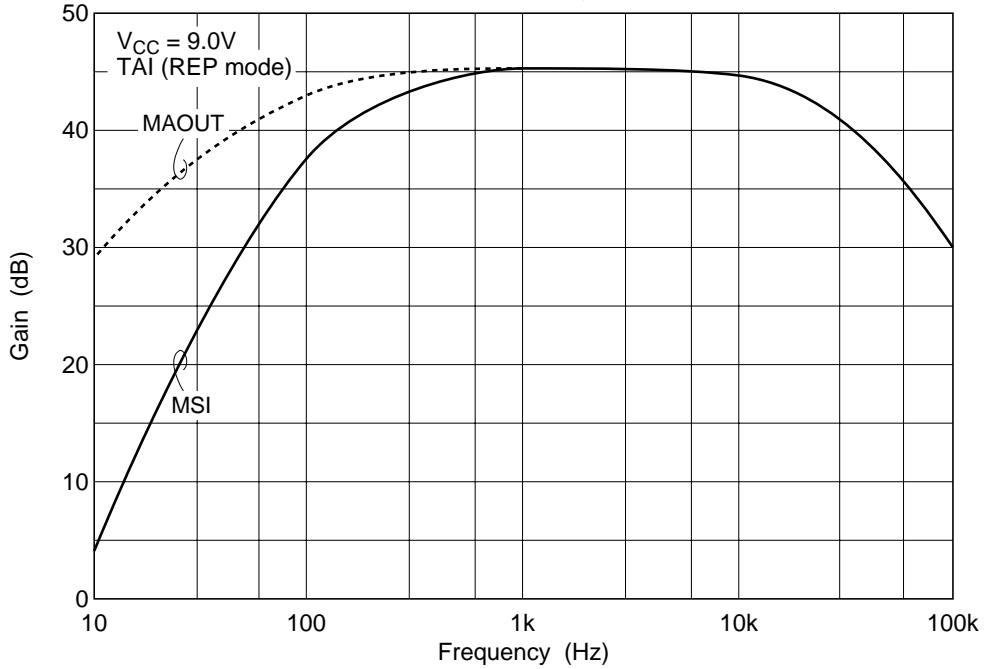


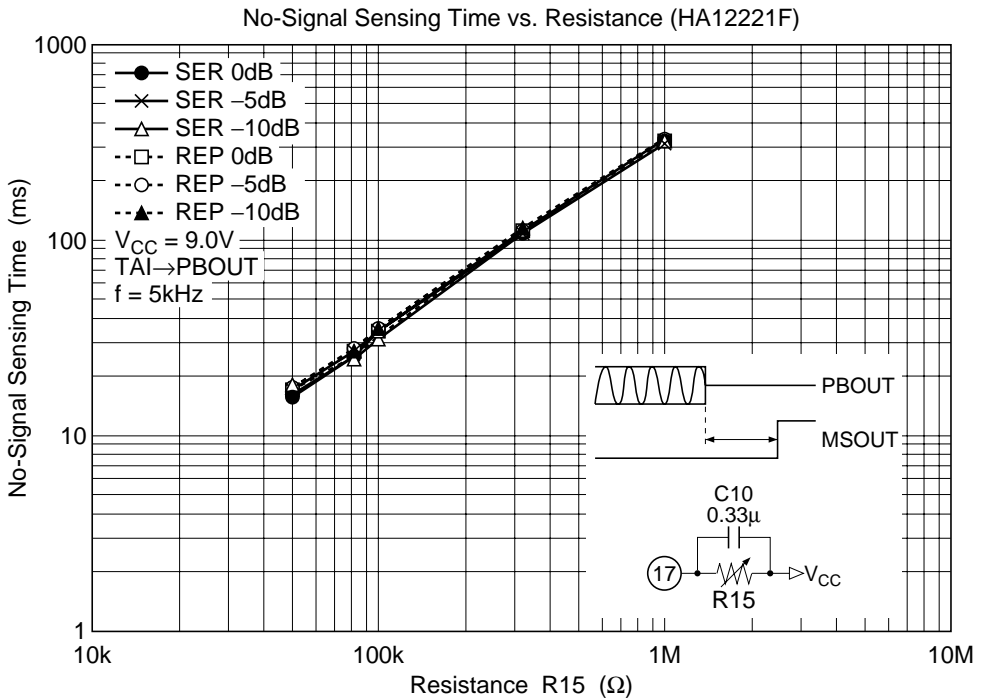
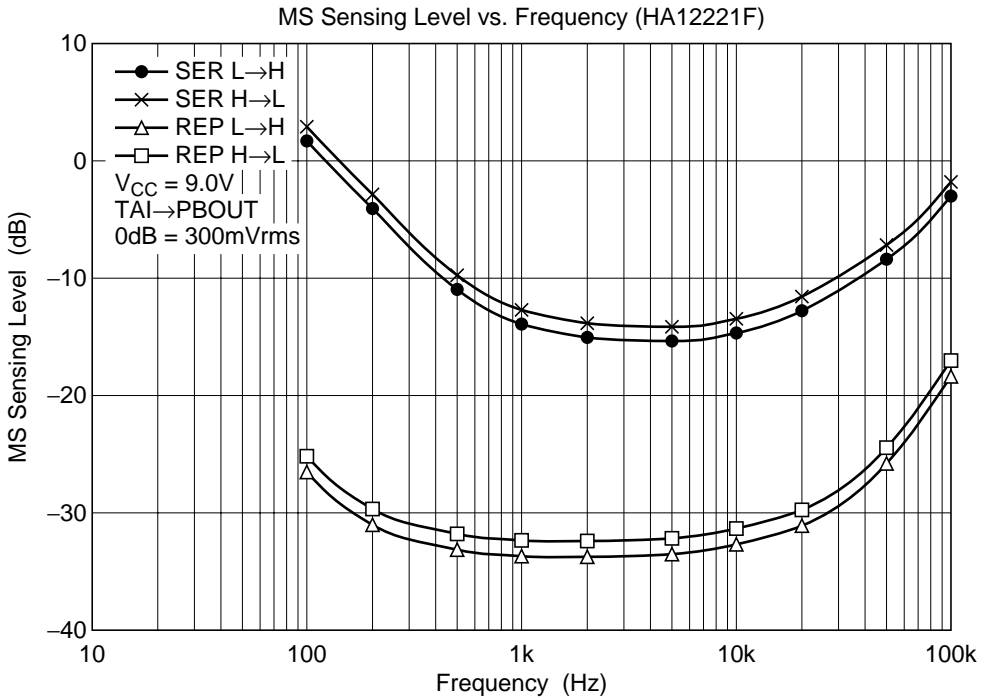


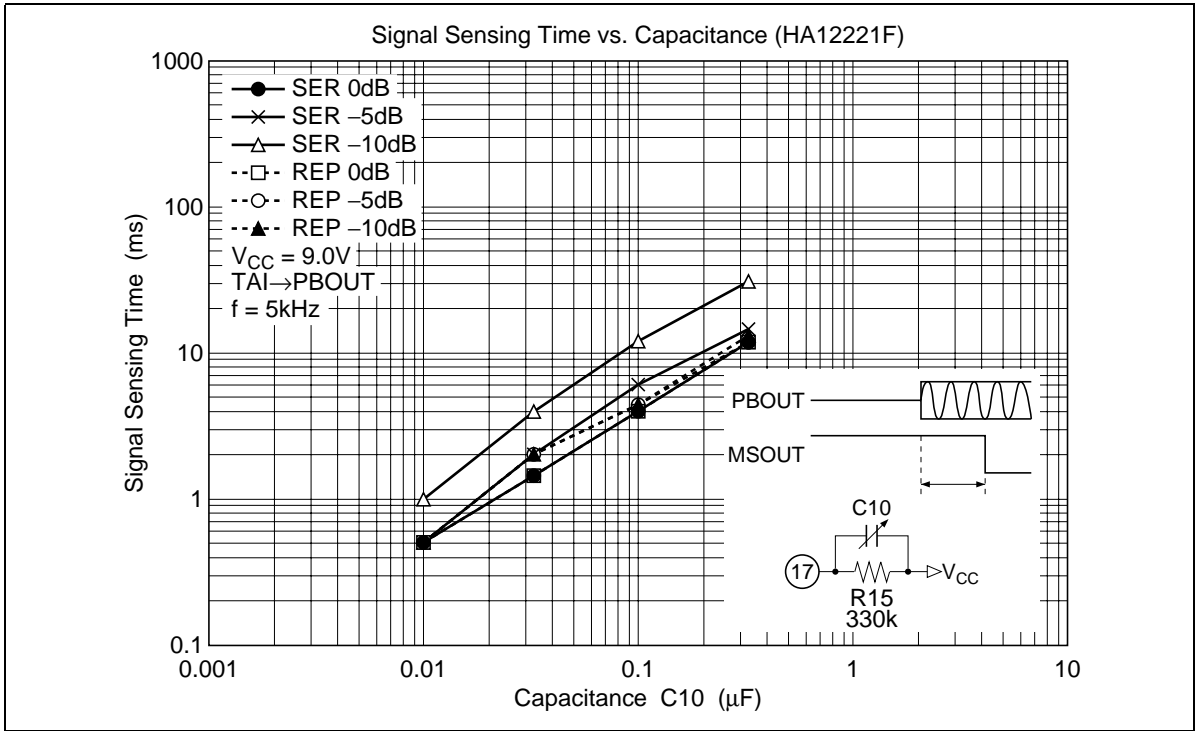
MS Amp. Gain vs. Frequency (HA12221F) (1)



MS Amp. Gain vs. Frequency (HA12221F) (2)



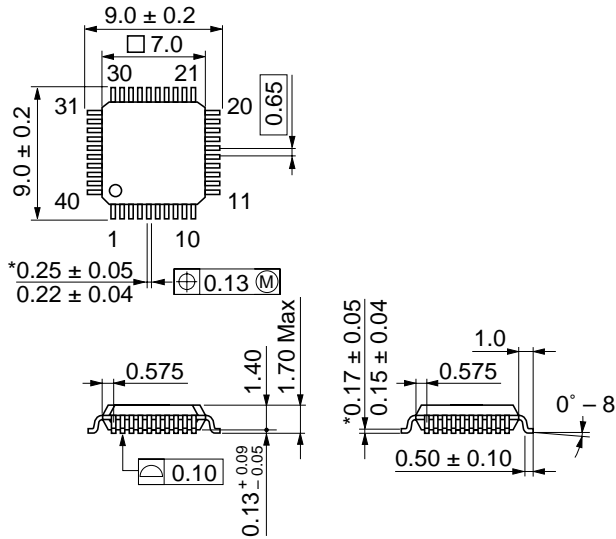




# HA12216F/HA12221F Series

## Package Dimensions

Unit: mm



\*Dimension including the plating thickness  
Base material dimension

Hitachi Code	FP-40B
JEDEC	—
EIAJ	Conforms
Mass (reference value)	0.2 g

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Semiconductor & Integrated Circuits.  
Nippon Bldg., 2-6-2, Ohte-machi, Chiyoda-ku, Tokyo 100-0004, Japan  
Tel: Tokyo (03) 3270-2111 Fax: (03) 3270-5109

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Hitachi Semiconductor  
(America) Inc.  
179 East Tasman Drive,  
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Hitachi Europe GmbH  
Electronic Components Group  
Dornacher Straße 3  
D-85622 Feldkirchen, Munich  
Germany  
Tel: <49> (89) 9 9180-0  
Fax: <49> (89) 9 29 30 00  
  
Hitachi Europe Ltd.  
Electronic Components Group.  
Whitebrook Park  
Lower Cookham Road  
Maidenhead  
Berkshire SL6 8YA, United Kingdom  
Tel: <44> (1628) 585000  
Fax: <44> (1628) 585160

Hitachi Asia Ltd.  
Hitachi Tower  
16 Collyer Quay #20-00,  
Singapore 049318  
Tel : <65>-538-6533/538-8577  
Fax : <65>-538-6933/538-3877  
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Hitachi Asia Ltd.  
(Taipei Branch Office)  
4/F, No. 167, Tun Hwa North Road,  
Hung-Kuo Building,  
Taipei (105), Taiwan  
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Hitachi Asia (Hong Kong) Ltd.  
Group III (Electronic Components)  
7/F., North Tower,  
World Finance Centre,  
Harbour City, Canton Road  
Tsim Sha Tsui, Kowloon,  
Hong Kong  
Tel : <852>-(2)-735-9218  
Fax : <852>-(2)-730-0281  
URL : <http://www.hitachi.com.hk>

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